HD 63701 X0P (A,I

8-Bit CMOS Microcomputer (ZTAT)

(iii) HITACHI

SHEET

The HD63701X0 is a high performance 8-bit CMOS single chip microcomputer unit (MCU) which, including 4k bytes of PROM, is pin compatible with the HD6301X0.

The HD63701X0 contains 4k bytes of PROM, 192 bytes of RAM, serial communication interface and 53 parallel I/O pins in addition to CPU. It includes functions of halt, memory ready, low speed access and releasing external bus at system expansion.

The HD63701X0 is available in a 64-pin shrunk plastic package. It can be programmed in the same procedure as 2732A type EPROM.

FEATURES

- Instruction Set Compatible with the HD6301X0 .
- 4k Bytes of PROM (compatible with 2732A type) •
- 192 Bytes of RAM
- 53 Parallel I/O Pins
- 24 I/O Common Pins (Port 2, 3, 6) 21 Output Pins (Port1, 4, 7)
- 8 Input Pins (Port 5)
- Driving Darlington Transistor (Port 2, 6)
- 16-bit Programmable Timer Input Capture Register x 1 Free Running Counter x 1 Output Compare Register x 2
- 8-bit Reloadable Timer **External Event Count** Spare Wave Occurrence
- Serial Communication Interface (SCI) Asynchronous Mode/Clock Synchronous Mode **3 Transfer Formats (Asynchronous Mode) 6 Clock Sources**
- Memory Ready for Low Speed Memory Access
- Halt
- Error-Detection (Address Error, Op-code Error)
- Interrupts 3 External, 7 Internal .
- Operation Mode .

peration mou		
	⊢ Mode 1 –	Expanded
MCU Mode		(Internal ROM Inhibited)
	- Mode 2 -	Expanded (Internal ROM Valid)
	LMode 3 –	Single-chip Mode
DDOLLAR .		-

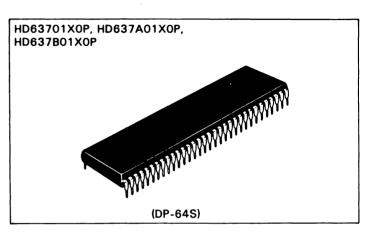
PROM Mode

- Up to 65k Bytes of Address Space •
- Low Power Dissipation Mode
- Sleep

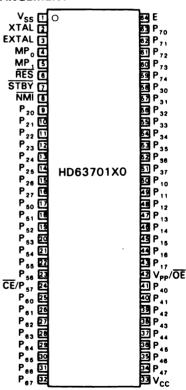
Standby

Minimum Instruction Execution Time -0.5μ s (f=2.0MHz)

Wide Operation Range f=0.1 to 1.0MHz; HD63701X0 $V_{CC} = 5V \pm 10\%$ f=0.1 to 1.5MHz; HD637A01X0 Lf=0.1 to 2.0MHz; HD637B01X0



PIN ARRANGEMENT

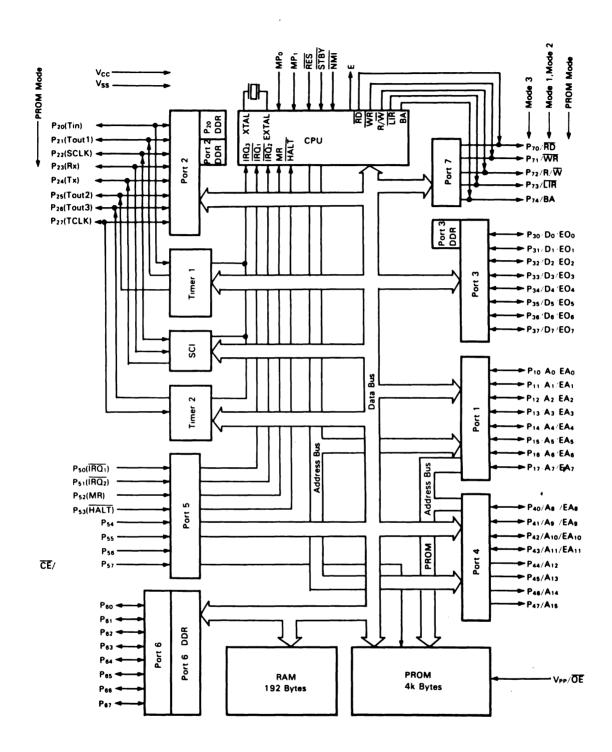


(Top View)



HD63701X0P,HD637A01X0P,HD637B01X0P -

BLOCK DIAGRAM



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ABSOLUTE MAXIMUM RATINGS

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Item	Symbol	Value	Unit
Supply Voltage	v _{cc}	-0.3~+7.0	v
Program Voltage	V _{PP}	-0.3 ~ 22	v
Input Voltage	V _{in}	$-0.3 \sim V_{CC} + 0.3$	v
Operating Temperature	T _{opr}	0~+70	°C
Storage Temperature	T _{stg}	-55 ~ +125	°C

(Note) This product has protection circuits in input terminal from high static electricity voltage and high electric field. But be careful not to apply overvoltage more than maximum ratings to these high input impedance protection circuits. To assure the normal operation, we recommend Vin, Vout: VSS≤ (Vin or Vout)≤ VCC.

MCU ELECTRICAL CHARACTERISTICS

• DC CHARACTERISTICS (V_{CC} = 5V±10%, V_{SS} = V_{PP} = 0V, Ta = 0 \sim +70°C, unless otherwise noted.)

Item		Symbol	Test Condition	min	typ	max	Unit
	RES, STBY, MP0, MP1			V _{CC} -0.5	-		
Input "High" Voltage	EXTAL	V		V _{CC} ×0.7	_		v
input nigh voltage	P ₂₂ (SCLK)***	V _{IH}		2.4		V _{CC} +0.3	v
	Other Inputs			2.2	_		
Input "Low" Voltage	All Inputs	V _{IL}		-0.3	-	0.8	V
Input Leakage Current	NMI, RES, STBY, MPo, MP1, Port 5	_{in}	V_{in} =0.5 ~ V_{CC} -0.5V	-	_	1.0	μA
Three State (off-state) Leakage Current	Ports 1, 2, 3, 4, 6, 7	I _{TSI}	V_{in} =0.5 ~ V_{CC} -0.5V	-	-	1.0	μA
Output //High// Malaga		M	Ι _{ΟΗ} =-200μΑ	2.4	-	-	v
Output "High" Voltage	All Outputs	V _{он}	I _{OH} =-10μA	V _{CC} -0.7	-	-	V
	Ports 2, 6			_	-	0.5	V
Output "Low" Voltage	Other Outputs	VOL	I _{OL} =1.6mA	-		0.4	V
Darlington Drive Current	Ports 2, 6	-I _{ОН}	V _{out} =1.5V	1.0	-	10.0	mA
Input Capacitance	All Inputs (Except V _{PP} /OE)	C _{in}	V _{in} =0V, f=1MHz, Ta=25°C	_	-	12.5	pF
	VPP /OE			-	_	25	pF
Standby Current	Non Operation	I _{STB}		-	3.0	15.0	μA
			Sleeping (f=1MHz**)		1.5	3.0	mA
		ISLP	Sleeping (f=1.5MHz**)	-	2.3	4.5	mA
Current Dissipation*			Sleeping (f=2MHz**)		3.0	6.0	mA
			Operating (f=1MHz**)	· _	7.0	10.0	mA
		Icc	Operating (f=1.5MHz**)	_	10.5	15.0	mA
			Operating (f=2MHz**)	-	14.0	20.0	mA
RAM Standby Voltage		VRAM		2.0			V

*VIH min = V_{CC}-1.0V, VIL max = 0.8V (All output terminals are at no load.)

*Current Dissipation of the operating or sleeping condition is proportional to the operating frequency. So the typ. or max, values about Current Dissipations at x MHz operation are decided according to the following formula;

typ. value (f = x MHz) = typ. value (f = 1MHz) x x max. value (f = x MHz) = max. value (f = 1MHz) x x

***Synchronous clock input use only.

🕲 НІТАСНІ

• AC CHARACTERISTICS (V_{CC} =5V±10%, V_{SS} = V_{PP} =0V, Ta=0 ~ +70°C, unless otherwise noted.)

BUS TIMING

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ltem		Sumbol	Test	HC	063701	X0	HD	637A01	1 X 0	HD	637B0	1X0	
item		Symbol	Condition	min	typ	max	min	typ	max	min	typ	max	Unit
Cycle Time		t _{cyc}		1	_	10	0.666	-	10	0.5	-	10	μs
Enable Rise Time		t _{Er}			-	25	-	-	25	_	-	25	ns
Enable Fall Time		t _{Ef}		-	-	25	-	-	25	-	_	25	ns
Enable Pulse Width "Hi	gh" Level*	PWEH		450	-	-	300	-	-	220	-	-	ns
Enable Pulse Width "Lo	w" Level*	PWEL		450	_	-	300	-	-	220	-	-	ns
Address, R/W Delay Tin	ne*	t _{AD}		-	-	250	-	-	190	-	_	160	ns
Data Delay Time	Write	todw		_	-	200	-	_	160	-	_	120	ns
Data Set-up Time	Read	t _{DSR}	F := 1	80	-	-	70	-	-	70	-	-	ns
Address, R/W Hold Tim	ie*	t _{AH}	Fig. 1	70	-	-	45	-	-	30	-	_	ns
Data Hold Time	Write*	t _{HW}		70	-	-	50	-	-	35	-	_	ns
Data Hold Time	Read	t _{HR}		0	1	-	0	1	_	0	-	_	ns
RD, WR Pulse Width*	· · ·	PWRW	-	450	-	-	300	-	-	220	-	-	ns
RD, WR Delay Time		tRWD		-	-	40	-	-	40	_	_	40	ns
RD, WR Hold Time		tHRW		-	-	30	-	-	30	-	-	25	ns
LIR Delay Time		TOLR		-	_	200	-	-	160	-	-	120	ns
LIR Hold Time		t _{HLR}		10	-	_	10	-	-	10	-	-	ns
MR Set-up Time*		t _{SM R}		400	-	-	280	_	-	230	_	-	ns
MR Hold Time*		tнмя	Fig. 2	-	-	90	-	-	40	-	-	0	ns
E Clock Pulse Width at	MR	PWEMR		_	_	9	-	-	9	-	_	9	μs
Processor Control Set-up Time		t _{PCS}	Fig. 3, 10, 11	200	_	-	200	-	-	200	-	-	ns
Processor Control Rise Time		t _{PCr}	5.00	-	-	100		-	100	-	-	100	ns
Processor Control Fall Time		tPCf	Fig. 2, 3	_	_	100	-	-	100	-	-	100	ns
BA Delay Time		t _{BA}	Fig. 3		_	250	-	_	190		_	160	ns
Oscillator Stabilization	Time	t _{RC}	Fig. 11	20	_	_	20	_	-	20	-	_	ms
Reset Pulse Width		PWRST		3		_	3	_		3		-	t _{cyc}

• These timings change in approximate proportion to t_{CVC}. The figures in this characteristics represent those when t_{CVC} is minimum (= in the highest speed operation).

PERIPHERAL PORT TIMING

ltem		Symbol	Test	HD63701X0		HD637A01X0			HD637B01X0			Unit		
		Symbol	Condition	min	typ	max	min	typ	max	min	typ	max		
Peripheral Data Set-up Time	Port	s 2, 3, 5, 6	tpdsu	Fig. 5	200	-	-	200	÷	-	200	_	-	ns
Peripheral Data Hold Time	Port	s 2, 3, 5, 6	t _{PDH}	Fig. 5	200	-	-	200	-	-	200	_	-	ns
Delay Time (Enal Negative Transitio Peripheral Data V	on to	Ports 1, 2, 3, 4, 6, 7	t _{PWD}	Fig. 6	-	-	300	_	-	300	_	-	300	ns

TIMER, SCI TIMING	TI	M	E	R	SCI	TIN	AIN	G
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	tem	Symbol	Test	нс	63701	X0	н	D637A0	01X0	НD	637B01	X0	11-14
		Symbol	Condition	min	typ	max	min	typ	max	min	typ	max	Unit
Timer 1 Input	t Pulse Width	1 TPWT	Fig. 8	2.0	-	-	2.0	-	-	2.0	-	-	t _{cyc}
	nable Positive Timer Output)	t _{TOD}	Fig. 7	-	-	400	_	1	400	-	_	400	ns
SCI Input	Async. Mode		Fig. 8	1.0	_	-	1.0	-	_	1.0	-	-	t _{cyc}
Clock Cycle	Clock Sync.	t _{Scyc}	Fig. 4, 8	2.0	-	-	2.0	_	-	2.0	-	-	t _{cyc}
SCI Transmit Time (Clock S		txD		-	-	200	-	_	200	-	-	200	ns
SCI Receive D Time (Clock S		t _{SRX}	Fig. 4	290	-	-	290	-	-	290	-	-	ns
SCI Receive D (Clock Sync.	Data Hold Time Mode)	t _{HRX}		100	-	_	100	_	-	100	-	-	ns
SCI Input Clo	ock Pulse Width	t _{PWSCK}		0.4	_	0.6	0.4	_	0.6	0.4	-	0.6	t _{Scyc}
Timer 2 Input	t Clock Cycle	t _{tcyc}		2.0	-	-	2.0	-	-	2.0	-	-	t _{cyc}
Timer 2 Input Width	t Clock Pulse	^t рwtck	Fig. 8	200	-	_	200	-	-	200	-	-	ns
Timer 1•2, SC Rise Time	CI Input Clock	t _{CKr}]	-	-	100	-	-	100	_	-	100	ns
Timer 1·2, SC Fall Time	CI Input Clock	t _{CKf}		_	-	100	-	_	100	_	_	100	ns

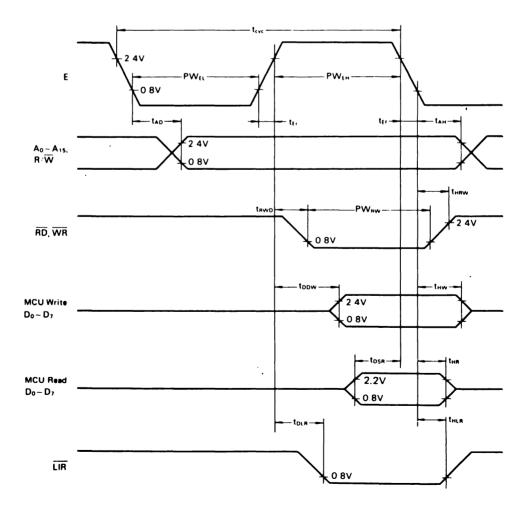


Figure 1 Mode 1, Mode 2 Bus Timing



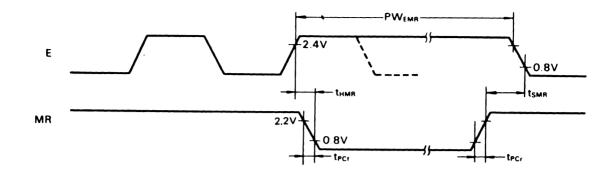


Figure 2 Memory Ready and E Clock Timing

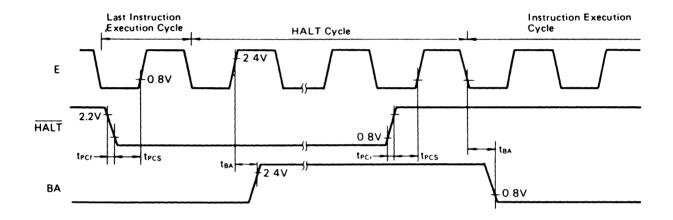


Figure 3 HALT and BA Timing

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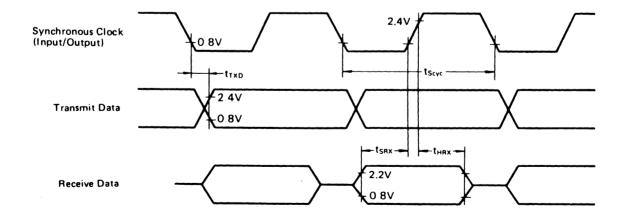


Figure 4 SCI Clocked Synchronous Timing



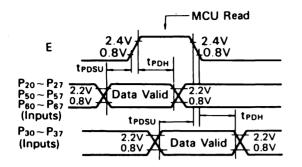
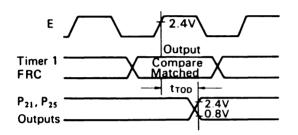
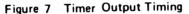


Figure 5 Port Data Set-up and Hold Times (MCU Read)



(a) Timer 1 Output Timing



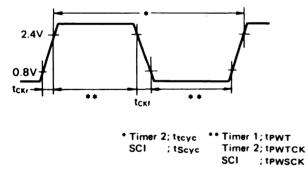


Figure 8 Timer 1.2, SCI Input Clock Timing

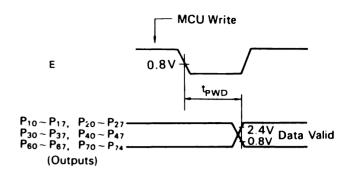
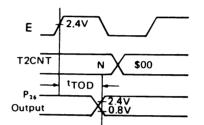
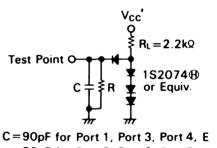


Figure 6 Port Data Delay Times (MCU Write)



(b) Timer 2 Output Timing



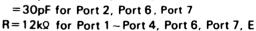


Figure 9 Bus Timing Test Loads (TTL Load)



HD63701X0P,HD637A01X0P,HD637B01X0P -

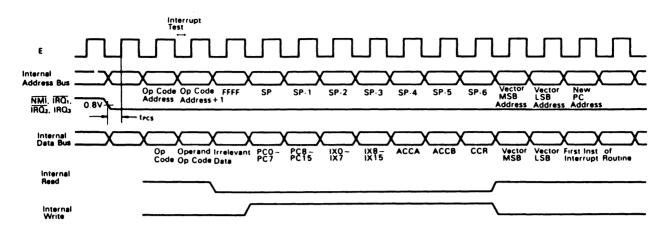


Figure 10 Interrupt Sequence

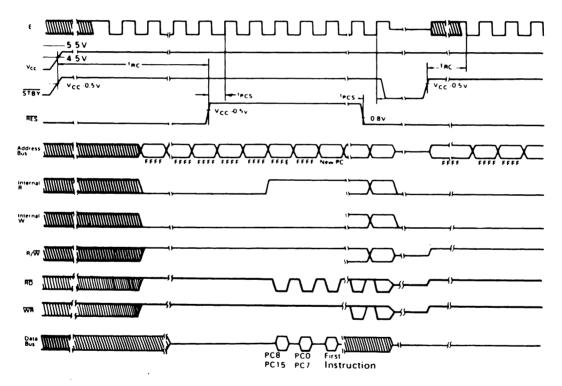


Figure 11 Reset Timing

" PROM PROGRAMMING ELECTRICAL CHARACTERISTICS

DC CHARACTERISTICS (V_{CC}=5V±10%,V_{PP}=21V±0.5V, V_{SS}=0V, Ta=25°C±5°C, unless otherwise noted.)

Item	Symbol	Test Condition	min	typ	max	Unit
Program Voltage	V _{PP}		20.5	21	21.5	V
Program Current	Ірр	V _{PP} =21V, <u>CE</u> =V _{IL}	-	_	30	mA
Input Leakage Current	I _{LI}	V _{in} =5.25V/0.4V	-		10	μA
Input "Low" Voltage	VIL		-0.1	-	0.8	V
Input "High" Voltage	VIH		2.2	-	V _{CC} +1.0	v
Output "Low" Voltage	V _{OL}	I _{OL} =1.6mA	-	-	0.45	V
Output "High" Voltage	V _{OH}	I _{OH} =-200μA	2.4	_	_	V

AC CHARACTERISTICS (V_{CC}=5V±10%,V_{PP}=21V±0.5V, V_{SS}=0V, Ta=25°C±5°C, unless otherwise noted.)

Item	Symbol	Test Condition	min	typ	max	Unit
Address Set-up Time	t _{AS}		2	-	-	μs
Address Hold Time	t _{AH}		0	-	-	μs
OE Set-up Time	tOES		2	-	-	μs
OE Hold Time	tOEH		2	-	-	μs
Data Set-up Time	t _{DS}		2	· -	-	μs
Data Hold Time	t _{DH}		2	-	-	μs
Output Disable Delay Time	tDF		0	-	130	ns
Data Valid from CE	t _{DV}	CE=VIL, OE=VIL	_	-	1	μs
CE Pulse Width	tpw	<u>}</u>	45	50	55	ms
OE Pulse Rise Time	tPRT		50	_		ns
V _{pp} Recovery Time	tvR		2	_	-	μs

(Note) tDF is defined when output becomes open because output level can not be refered.

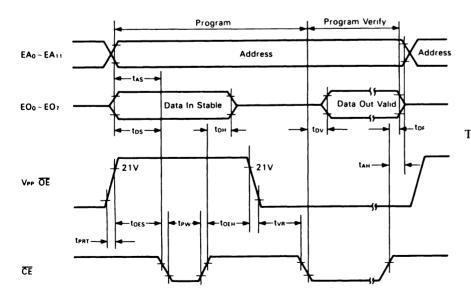


Figure 12 PROM Programming Timing



FUNCTIONAL PIN DESCRIPTION

• V_{cc}, V_{ss}

 V_{CC} and V_{SS} provide power to the MCU with $5V \pm 10\%$ supply. V_{SS} pin should be tied to ground.

• XTAL, EXTAL

These two pins interface a crystal (an AT-cut type). Divideby-four circuit is on chip. When 4MHz crystal is used, the system clock is 1MHz for example.

EXTAL pin may be driven with an external clock of 45 to 55% duty, and one fourth frequency of the external clock is produced in the LSI. The external clock frequency should be less

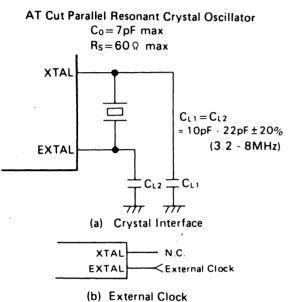


Figure 13 Connection Circuit

than four times of the maximum frequency. When using the external clock, XTAL pin should be open. Fig. 13 shows an example of connection circuit. The crystal and C_{L1} , C_{L2} should be mounted as close as possible to XTAL and EXTAL pins. Any line must not cross the line between the crystal and XTAL, EXTAL.

• STBY

This pin is used for standby mode or PROM mode.

In standby mode, the oscillation may be stopped. To retain the contents of RAM at standby, "0" should be written into RAM enable bit (RAMW). RAME is the bit 6 of the RAM/Port 5 control register at \$0014. RAM is disabled by this operation and its contents is sustained. Refer to "LOW POWER DISSIPA-TION MODE" for standby mode.

When this pin and Mode Program pins, MP_0 and MP_1 , are "Low" level, the MCU is in PROM mode. Refer to "THE PROM PROGRAMMING" for details.

Reset (RES)

This pin is used to reset the MCU's internal state and provide a startup procedure. During power up, RES pin must be held below "Low" level for more than 20 ms.

The CPU registers (accumulator, index register, stack pointer, condition code register except for interrupt mask bit), RAM and data registers of ports are not initialized during reset, so their contents are unknown in a startup procedure.

To reset the MCU during operation, RES should be held "Low" for at least 3 system-clock cycles. At the 3rd cycle, all the address buses become "High". When RES remains "Low", the address buses keep "High". If RES turns "High", the MCU re-

- (1) Latch the value of the mode program pins: MP_0 and MP_1 .
- (2) Initialize each internal register (refer to Table 5).
- (3) Set the interrupt mask bit. For the CPU to recognize the maskable interrupts $\overline{IRQ_1}$, $\overline{IRQ_2}$ and IRQ_3 , this bit should be cleared in advance.
- (4) Put the contents (=start address) of the last two addresses (\$FFFE, \$FFFF) into the program counter and start the program from this address. (Refer to Table 1).

• The MCU is unable to accept a reset input until the clock becomes normal oscillation after power on (max. 20ms). During this transient time, the MCU and I/O pins are undefined. Please be aware of this for system designing.

• Enable (E)

This pin provides a TTL-compatible clock used for bus synchronization. Its frequency is one fourth that of the internal oscillator or external clock. This pin can drive one TTL load and 90pF capacitance.

Non-Maskable Interrupt (NMI)

When the negative edge of the input signal is detected at this pin, the CPU will begin a non-maskable interrupt sequence. But the current instruction will be completed before it responds to the request. The interrupt mask bit of the condition code register doesn't affect non-maskable interrupt at all.

When the interrupt occurs, the contents of the program counter, the index register, the accumulators and the condition code register will be pushed onto the stack. Upon completion of this sequence, a vector is fetched from \$FFFC and \$FFFD, transferred their contents to the program counter and the non-maskable interrupt service routine starts. After reset, the stack pointer should be initialized on an appropriate memory area before NMI input.

Interrupt Request (IRQ , IRQ)

These are level-sensitive pins which request an internal interrupt sequence. At interrupt request, the CPU will complete the current instruction before it responds to the request. If the interrupt mask in the condition code register is clear, the CPU will begin an interrupt sequence; if set, the interrupt request will be ignored. When the sequence starts, the contents of the program counter, the index register, the accumulators and the condition code register will be pushed onto the stack, then the interrupt mask bit will be set and inhibits all maskable interrupt. Finally, a vector is fetched from an address depicted in Table 1 and transferred to the program counter, and instruction execution is resumed.

The external interrupt pins, $\overline{IRQ_1}$ and $\overline{IRQ_2}$ are also used for port pins P_{50} and P_{51} , so it is controlled by Bit 0 and 1 of the RAM/Port 5 control register at \$0014. Refer to "RAM/PORT 5 CONTROL REGISTER" for details.

One of the internal interrupts, ICI, OCI, TOI, CMI or SIO can generate an internal interrupt (IRQ_3) .. IRQ_3 function is just the same as $\overline{IRQ_1}$ or $\overline{IRQ_2}$ except the vector address. Fig. 14 shows the block diagram of the interrupt circuit.

Mode Program (MP₀, MP₁)

These two pins decide the operation mode. Refer to "MODE SELECTION" for more details.



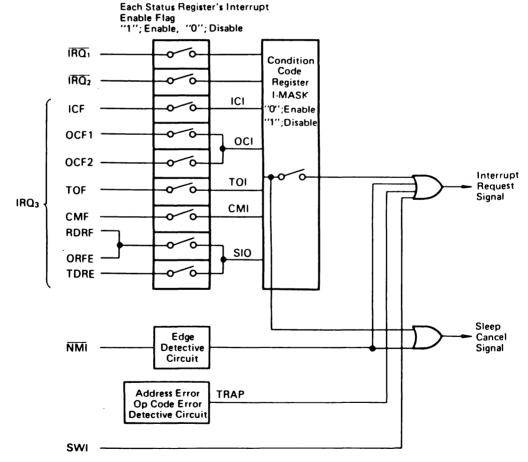
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Driarity	Ve	ctor	
Priority	MSB	LSB	Interrupt
Highest	FFFE	FFFF	RES
≜	FFEE	FFEF	TRAP
	FFFC	FFFD	NMI
	FFFA	FFFB	SWI (Software Interrupt)
	FFF8	FFF9	ĪRQ ₁
	FFF6	FFF7	ICI (Timer 1 Input Capture)
	FFF4	FFF5	OCI (Timer 1 Output Compare 1, 2)
	FFF2	FFF3	TOI (Timer 1 Overflow)
	FFEC	FFED	CMI (Timer 2 Counter Match)
Ļ	FFEA	FFEB	IRQ ₂
Lowest	FFF0	FFF1	SIO (RDRF+ORFE+TDRE)

Table 1 Interrupt Vector Memory Map

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The following signal descriptions are applied only for expanded mode.

Read/Write (R/W; P72)

This signal, usually in read state ("High"), shows whether the MCU is in read ("High") or write ("Low") state. This can drive one TTL load and 30pF capacitance.

• RD, WR (P₇₀, P₇₁) These outputs will turn "Low" when the CPU read/write operation is completed. This enables the CPU easy to access the peripheral LSI with RD and WR input pins. These pins can drive one TTL load and 30pF capacitance.

• Load Instruction Register (LIR; P73)

This is output for the instruction opecode on data bus (active low). This pin can drive one TTL load and 30pF capacitance.

• Memory Ready (MR; P₅₂)

This input is used to stretch the system clock's "High" period in order to access low-speed memories. During this signal being in "High", the system clock operates in normal sequence. But in "Low", the "High" period of the system clock will be stretched in integral multiples of the cycle time. This allows the CPU to interface with low-speed memories (See Fig. 2). Up to 9μ s can be stretched.

During internal address access or nonvalid memory access, MR is prohibited internally to prevent decrease of operation speed. Even in the halt state, MR can also stretch "High" period of system clock to allow peripheral devices to access low-speed memories. As this pin is used also for P₃₂, an enable bit is provided at bit 2 of the RAM/Port 5 control register at \$0014. Refer to "RAM/PORT 5 CONTROL REGISTER" for more details.

• Halt (HALT; P₅₃)

This input is used to stop instruction execution or to release buses free. When this signal turns "Low", the CPU will be in the halt state after completing the current instruction. During the halt state, BA (P_{74}) is in "High", and an address bus, data bus, RD, WR and R/W are high impedance. When an interrupt is requested in the halt state, the CPU responds to the interrupt request after the halt is cancelled.

(Note) When the CPU is interrupt wait state in WAI instruction execution, HALT should be held "High". If HALT turns "Low", the CPU may malfunction after releasing the halt state.

Refer to "APPLICATION NOTES-Precaution for using WAI instruction" for more details.

• Bus Available (BA; P74)

This output is normally "Low" but "High" when the CPU accepts HALT and releases the buses. The HD6800 and HD6802 make BA "High" and release the buses at WAI execution, while the HD63701X0 doesn't make BA "High" under the same condition.

The following pin functions are applied only in PROM mode. Refer to "THE PROM PROGRAMMING" for details of PROM mode.

Chip Enable (CE; P₅₇)

This pin is input for programming and verifying the PROM. When this pin is "Low" level, PROM will be enable.

The PROM can not be programmed or verified in "High" level.

Program Voltage/Output Enable (V_{PP}/OE)

This pin is used for program voltage and data output control in verification.

Data from Port 3 (EO₀ to EO₇) can be programmed into the

PROM when applying $21V \pm 0.5V$ to V_{pp} and holding \overline{CE} in "Low" level. The PROM address is provided to Port 1 and Port 4 (EA₀ to EA₁₁). In verification, the PROM data is output from Port 3 (EO₀ to EO₇) when this pin is "Low" level. In "High" level, Port 3 will be high-impedance. In MCU mode, this pin should be connected to V_{SS}.

PORT

The HD63701X0 has six 8-bit ports and a 5-bit port. Table 2 gives the address of ports and the data direction register and Fig. 15 the block diagrams of each port.

Table	2 Port and Data Dire	ection Register Address
Port	Port Address	Data Direction Register

Port	Port Address	Data Direction Register
Port 1	\$0002	-
Port 2	\$0003	\$0001
Port 3	\$0006	\$0004
Port 4	\$0007	_
Port 5	\$0015	-
Port 6	\$0017	\$0016
Port 7	\$0018	_

Port 1

In MCU mode, port 1 is used for an 8-bit output port. In mode 3, port 1 is high impedance during reset, and keeps the state even after reset is released. When the CPU writes on the port 1 data register, the written data will appear at Port 1. Once port 1 gets in the output state, it operates as an output till reset. The CPU can read the Port 1 data register for the bit manipulation instruction.

In mode 1 and 2, port 1 is used for lower address buses. This port can drive one TTL load and 90pF capacitance.

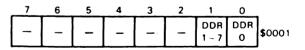
In PROM mode, port 1 is lower address bus $(EA_0 \text{ to } EA_7)$ for the PROM.

Port 2

An 8-bit input/output port. Its I/O state depends on the data direction register (DDR) of port 2 which provides two bits; bit 0 decides the I/O direction of P_{20} and bit 1 the I/O direction of P_{21} to P_{27} ("0" for input, "1" for output).

Port 2 is also used for the timers and the SCI. When used for the timers and the SCI, P_{21} to P_{27} are decided I/O regardless of the DDR (except for P_{20}).

Port 2 Data Direction Register



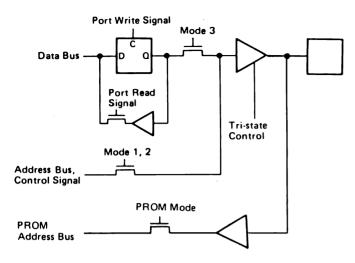
The DDR of port 2 is cleared at reset and port 2 is configured as an input. This port can drive one TTL and 30pF. In addition, it is capable of sinking 1mA current at Vout=1.5V to drive directly the base of Darlington transistors.

Port 3

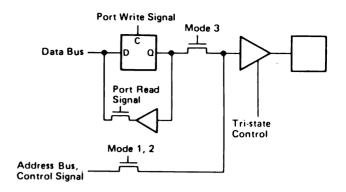
An 8-bit I/O port. I/O state depends on the DDR of Port 3 which has only one bit ("0" for input and "1" for output). It is cleared at reset. In mode 1 and 2, port 3 is used for data bus. This port can drive one TTL load and 90pF capacitance.

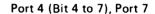
Port 3 is used for data bus $(EO_0 \text{ to } EO_7)$ of PROM in PROM mode. In this case, I/O state of Port 3 is selected by \overline{OE} but not the DDR.

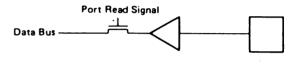




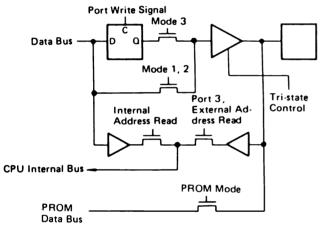
Port 1, Port 4 (Bit 0 to 3)



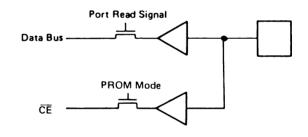




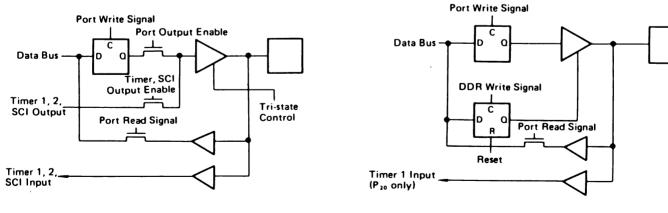
Port 5





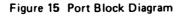






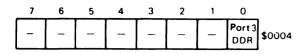
Port 2

Port 6, Port 2 (Bit 0)





Port 3 Data Direction Register



Port 4

In MCU mode, Port 4 is used for an 8-bit output port like Port 1. In mode 1 and 2, it is used for upper address bus.

In PROM mode, P_{40} to P_{43} are used for upper address bus (EA₈ to EA₁₁) of PROM.

Port 5

An 8-bit input port. The lower 4 bits are used for interrupt, MR, \overrightarrow{HALT} , and P_{57} is \overrightarrow{CE} for the PROM control.

Port 6

An 8-bit I/O port. This port is programmable as either input or output under software control of the corresponding the DDR ("0" for input, "1" for output). This port can drive one TTL load and 30pF. The DDR of Port 6 is cleared at reset. In addition, it is capable to sinking ImA current at Vout=1.5V to drive directly the base of Darlington transistors.

Port 7

A 5-bit output port. In mode 3, Port 7 is high impedance during reset and keeps the state even after reset is released. When the CPU writes on the Port 7 data register, the written data will appear at Port 7. Once Port 7 gets in the output state, it operates as an output till reset. The CPU can read the data register for the bit manipulation instruction. In this case b_7 to b_5 are "1".

In mode 1 and 2, Port 7 is used for control signals (\overline{RD} , \overline{WR} , $\overline{R/W}$, \overline{LIR} and BA). This port can drive one TTL load and 30pF.

RAM/PORT 5 CONTROL REGISTER

The control register located at \$0014 controls on-chip RAM and Port 5.

RAM/Port 5 Control Register

7	6	5	4	3	2	1	0	_
STBY PWR	RAME	-	-	HLTE	MRE	IRQ₂ E	IRQ1 E	\$0014

Bit 0, Bit 1 \overline{IRQ}_1 , \overline{IRQ}_2 Enable Bit (IRQ E, IRQ E)

When using P_{50} and P_{51} for interrupt pins, write "1" in these bits. When "0", the CPU doesn't accept an external interrupt or a sleep cancellation by the external interrupt. These bits are cleared at reset.

Bit 2 Memory Ready Enable Bit (MRE)

When using P_{52} for an input for Memory Ready signal, write "1" in this bit. When "0", the memory ready function is prohibited and P_{52} is for port. In mode 3, the memory ready function is prohibited regardless of the value of this bit. This bit is set at reset.

Bit 3 Halt Enable Bit (HLTE)

When using P_{53} for an input for Halt signal, write "1" in this bit. When "0", the halt function is prohibited. In mode 3, the

halt function is prohibited regardless of the value of this bit. This bit is set at reset.

(Note) When using P_{52} and P_{53} for port in mode 1 and 2, MRE and MLTE must be cleared after reset. If P_{52} or P_{53} turns "Low" before MRE and HLTE are cleared, the memory ready function or the halt function will not be prohibited.

Bit 4, Bit 5 Not Used.

Bit 6 RAM Enable (RAME)

The RAM is controlled by this bit. It is set at reset and the RAM is enabled. This bit is programmable by software. When the RAM is disabled (=logic "0"), the CPU can access an external memory. This bit should be cleared at the beginning of standby mode to protect the RAM data.

Bit 7 Standby Power Bit (STBY PWR)

This bit is cleared whenever V_{CC} decreases below V_{RAM} (min). This is a read/write status bit by software. If this bit is set before standby mode, it indicates that V_{CC} is applied and the RAM is valid.

MODE SELECTION

The HD63701X0 provides two fundamental modes, MCU mode and PROM mode. MCU mode is grouped into three; two expanded modes (mode 1, mode 2) and a single chip mode (mode 3).

These operating modes are selectable by mode program pins, MP_0 and MP_1 , and standby pin, \overline{STBY} as shown in Table 3.

• Mode 1 (Expanded Mode)

In this mode, Port 3 is data bus, Port 1 is lower address bus and Port 4 is upper address bus to interface with the HMCS6800 buses. Port 7 is used for control signal such as R/\overline{W} . In mode 1, the PROM is disable and external address space are expandable up to 65k bytes (refer to Fig. 16).

• Mode 2 (Expanded Mode)

This mode is also expanded mode. But in mode 2, address space is expandable up to 61k bytes and the PROM is enable (refer to Fig. 17).

• Mode 3 (Single-chip Mode)

In this mode, all ports are available (refer to Fig. 18).

PROM Mode

In this mode, the PROM can be programmed. Refer to "THE PROM PROGRAMMING" for details.

Mode and Ports

Table 4 shows the MCU signals in each mode.

Mode		· MP1	MPo	STBY	PROM	RAM	Interrupt Vector	Operation Mode
	1	"L"	"н"	*	E	(Note 1)	E	Expanded Mode
MCU Mode	2	"н"	"L"	*	I	(Note 1)	I	Expanded Mode
	3	"Н"	"н"	*	I	I	1	Single-chip Mode
PROM Mode		"L"	"L"	"L"	I	*	*	PROM Programming Mode

"L"=Logic "0", "H"=Logic "1", I; Internal, E; External, *; Don't care

(Note 1) The RAM address area will be external by clearing RAME bit at \$0014.

Mode		MCU Mode			
Port	Mode 1	Mode 2	Mode 3	PROM Mode	
Port 1	Address Bus (Ao \sim A7)	Address Bus (A $_0 \sim A_7$)	Output Port	Address Bus (EAo ~ EA7)	
Port 2	I/O Port	I/O Port	I/O Port	No use (Note 3)	
Port 3	Data Bus (Do ~D7)	Data Bus (Do ~D7)	I/O Port	Data Bus (EOo ~ EO7)	
Port 4	Address Bus (A8 ~ A15)	Address Bus (A8 \sim A15)	Output Port	Address Bus (EAs ~EA11) (Note 1)	
Port 5	Input Port	Input Port	Input Port	CE (P ₅₇) (Note 2)	
Port 6	I/O Port	I/O Port	I/O Port	No use (Note 3)	
Port 7	RD, WR, R/W, LIR, BA	RD, WR, R/W, LIR, BA	Output Port	No use (Note 3)	

Table 4 MCU Signals in Each Mode

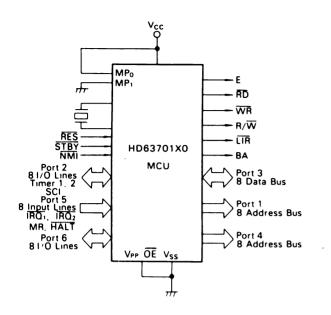
(Note 1) Use only 4 pins P40 to P43. P44 to P47 are not used.

(Note 2) 7 pins P₅₀ to P₅₆ are not used.

(Note 3) Unused ports should be connected to V_{SS}.

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HD63701X0P,HD637A01X0P,HD637B01X0P-





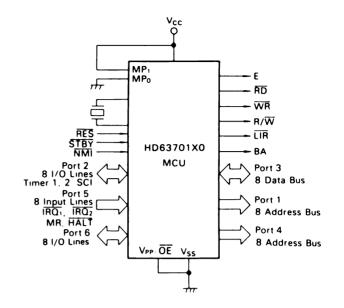


Figure 17 MCU Mode; Mode 2

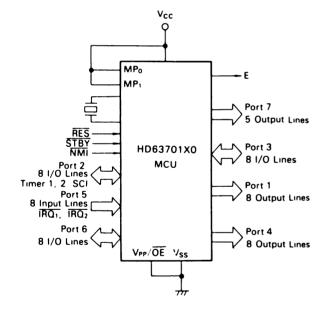


Figure 18 MCU Mode; Mode 3

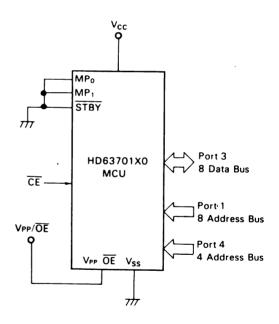


Figure 19 PROM Mode

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MEMORY MAP

The MCU has ability to access a 65k byte memory space depending on the operating mode. A memory map for each operating mode is shown in Fig. 20. The first 32 locations of each map are reserved for the MCU's internal register area, as shown in Table 5.

Address	Registers	R/W***	Initialize at RESET
00	-	_	_
01	Port 2 Data Direction Register	w	\$FC
02*	Port 1	R/W	Undefined
03	Port 2	R/W	Undefined
04*	Port 3 Data Direction Register	w	\$FE
05	-	-	_
06*	Port 3	R/W	Undefined
07*	Port 4	R/W	Undefined
08	Timer Control/Status Register 1	R/W	\$00
09	Free Running Counter ("High")	R/W	\$00
0A	Free Running Counter ("Low")	R/W	\$00
08	Output Compare Register 1 ("High")	R/W	\$FF
0C	Output Compare Register 1 ("Low")	R/W	\$FF
0D	Input Capture Register ("High")	R	\$00
0E	Input Capture Register ("Low")	R	\$00
0F	Timer Control/Status Register 2	R/W	\$10
10	Rate, Mode Control Register	R/W	\$00
11	Tx/Rx Control Status Register	R/W	\$20
12	Receive Data Register	R	\$00
13	Transmit Data Register	w	\$00
14	RAM/Port 5 Control Register	R/W	\$7C or \$FC
15	Port 5	R	-
16	Port 6 Data Direction Register	w	\$00
17	Port 6	R/W	Undefined
18*	Port 7	R/W	Undefined
19	Output Compare Register 2 ("High")	R/W	\$FF
1A	Output Compare Register 2 ("Low")	R/W	\$FF
1B	Timer Control/Status Register 3	R/W	\$20
1C	Time Constant Register	w	\$FF
1D	Timer 2 Up Counter	R/W	\$00
1E	-	_	-
1F**	Test Register	_	-

Table 5	Internal	Register
	Internat	negiater

* External Address in Mode 1, 2.

Test Register. Do not access to this register.
 R : Read Only Register
 Write Only Register

R/W: Read/Write Register

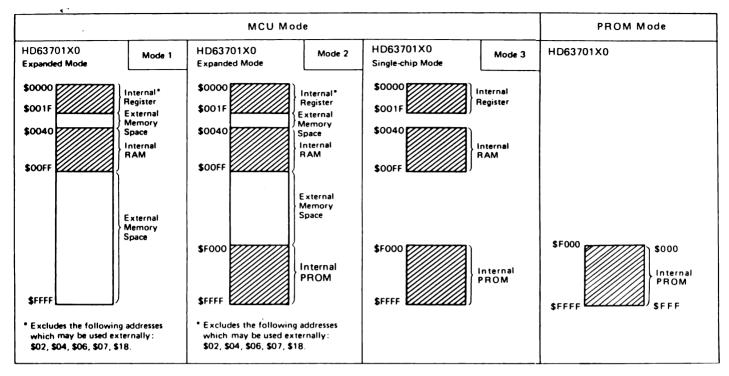


Figure 20 HD63701X0 Memory Map

THE PROM PROGRAMMING

The HD63701X0 does not operate as the MCU in PROM mode, which allows to be programmable as equivalent EPROM 2732A type. When three pins, MP₀, MP₁ and STBY should be held low, the MCU will be in PROM mode as shown in Table 3. In this mode, P_{30} to P_{37} are used for data bus, P_{10} to P_{17} and P_{40} to P_{43} for address bus, and P_{57} for CE input. (refer to Fig. 19.).

Programming/Verification

When \overline{CE} pin is held low after the program voltage (V_{PP}) is applied to V_{PP}/ \overline{OE} pin, the data byte can be applied to Port 3. When V_{PP}/ \overline{OE} pin and \overline{CE} pin are held low after programming, the programmed data is output from Port 3 and user can verify the data. I/O timing of these signals are referred to Fig. 12.

When \overline{CE} pin is returned to high, Port 3 will be tri-state and

PROM programming/verification will be inhibited.

Table 6 shows the condition of the each pin is PROM mode. Unused pins should be connected to GND in PROM mode.

(Note) It is impossible to erase the programmed PROM of the plastic molded HD63701X0.

Refer to "APPLICATION NOTES-The PROM Programming and Maintenance" for details.

TIMER 1

The HD63701X0 has a 16-bit programmable timer which can be used to perform input waveform measurements while generating two independent output waveforms. The pulse width can vary from several microseconds to many seconds.

Timer 1 is configurated as follows (refer to Fig. 22).

Pin	v _{cc}	v _{ss}	V _{PP} /OE	ĈĒ	P30 to P37	P10 to P17 P40 to P43	MP0, MP1, STBY	Other pins
No. Mode	33	1	42	24	51 to 58	43 to 50 38 to 41	4, 5, 7	
Programming	+5	GND	V _{PP}	"L"	Data input	Address input	"L"	GND
Verification	+5	GND	"L"	"L"	Data output	Address input	"L"	GND
Inhibition of programming/verification	+5	GND	Don't care	"Н"	High impedance	Don't care	"L"	GND

Table 6 Pin Condition in PROM mode

"H"; VIH level, "L": VIL level

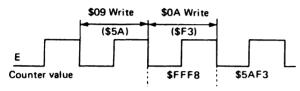
- Control/Status Register 1 (8 bit)
- · Control/Status Register 2 (7 bit)
- Free Running Counter (16 bit)
- Output Compare Register 1 (16 bit)
- Output Compare Register 2 (16 bit)
- · Input Capture Register (16 bit)

• Free-Running Counter (FRC) (\$0009 : 000A)

The key timer element is a 16-bit Free-Running Counter which is incremented by system clock (E). The counter value is readable by software without affecting the FRC. It is cleared by reset.

A write to the high byte of the FRC (\$09) will preset the high and low byte of the FRC to \$FFF8. A continuous write to the high and low byte FRC, however, will set them to the write data.

The FRC write timing will be as follows when double store instructions (STD, STX etc.) execute.



In the case of a write (\$5AF3) to the FRC.

Figure 21 Counter Write Timing

Output Compare Register (OCR) (\$000B, \$000C; OCR1) (\$0019, \$001A; OCR2)

The Output Compare Register is a 16-bit read/write register used to control an output waveform. It is always compared with the FRC on each E-cycle.

When a match is found, Output Compare Flag (OCF) in the Timer Control/Status Register (TCSR) is set. If an output enable bit (OE) in the TCSR2 is "1", an output level bit (OLVL) in the TCSR will appear at Port 21 (Tout 1) or Port 25 (Tout 2).

The OCR and OLVL can then be changed for the next compare. The OCR is set to \$FFFF at reset. The compare function is inhibited for a cycle after a write to the OCR or to the high byte of the FRC. This is to set the 16-bit value valid in the register for compare. In addition, it is because \$FFF8 is set at the next cycle of a write to the high byte of the FRC.

• For a write to the FRC or the OCR, 2-byte transfer instruction (such as STX etc.) should be used.

Input Capture Register (ICR) (\$000D : 000E)

The Input Capture Register is a 16-bit read only register used to store the FRC when an external input transition occures defined by input edge bit (IEDG) in the TCSR1.

In order to input the external signal to the edge detective circuit, Port 20 should be configured as an input. When an input capture occures at the next cycle of a read the high-byte of the ICR, the input capture will delay one cycle. In order to ensure the input capture, a read to the ICR needs 2-byte transfer instruction, and the input pulse width should be at least 2 system cycles. This register is cleared (\$0000) at reset.

• Timer Control/Status Register 1 (TCSR1) (\$0008)

The Timer Control/Status Register 1 is an 8-bit register of which all bits are readable while the lower 5 bits can be written. The upper 3 bits indicate the following timer's status.

- Bit 5 The FCR has overflowed. (TOF).
- Bit 6 A match has been found between the FCR and the OCR 1 (OCF1).
- Bit 7 A level transition of the timer input has been detected (ICF).

The followings are each bit descriptions.

Timer Control/Status Register 1

7	6	5	4	3	2	1	0	
ICF	OCF 1	TOF	EICI	EOCI1	ETOI	IEDG	οινιι	\$0008

Bit 0 OLVL1 Output Level 1 When a match is found between the FCR and the OCR1, OLVL1 will appear at Port 21 if OE1, bit 0 of the TCSR2, is set.

- Bit 1 IEDG Input Edge This bit controls which level transition will trigger the FCR transfer to the ICR. For this function, the DDR corresponding to Port 20 should be cleared. IEDG=0, transferred on a negative edge
 - IEDG=1, transferred on a positive edge
- Bit 2 ETOI Enable Timer Overflow Interrupt When this bit is set, an internal interrupt (IRQ₃) is enabled for TOI. When cleared, the interrupt is inhibited.
- Bit 3 EOCI1 Enable Output Compare Interrupt 1 When this bit is set, an internal interrupt (IRQ₃) is enabled for OCI1. When cleared, the interrupt is inhibited.
- Bit 4 EICI Enable Input Capture Interrupt When this bit is set, an internal interrupt (IRQ_a) is enabled for ICI. When cleared, the interrupt is inhibited.
- Bit 5 TOF Timer Overflow Flag This read only bit is set when the FCR contains all 1's. It is cleared by reading the TCSR1 followed by the FCR's high byte (\$0009).
- Bit 6 OCF1 Output Compare Flag 1

This read only bit is set when a match is found between the OCR1 and the FRC. It is cleared by writing to the OCR1 (\$000B or \$000C) followed by reading the TCSR1 or TCSR2.

Bit 7 ICF Input Capture Flag This read only bit is set to indicate a level transition defined by IEDG. It is cleared by reading the high byte (\$000D) of the ICR followed by the TCSR1 or TCSR2.

Timer Control/Status Register 2 (TCSR2) (\$000F)

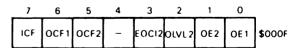
The Timer Control/Status Register 2 is a 7-bit register. All bits are readable while the lower 4 bits can be written. The upper 3 bits indicate the following timer's status.

Bit 5 A match has been found between the FRC and the OCR2 (OCF2).

- Bit 6 The same flag as the OCF1 of the TCSR1.
- Bit 7 The same flag as the ICF of the TCSR1.

The followings are each bit descriptions.

Timer Control/Status Register 2



Bit 0 OE1 Output Enable 1

If this bit is set, the OLVL1 will appear at Port 21 when a match is found between the FCR and the OCR1. When it is cleared, Port 21 will be I/O port. When set, it will be an output of OLVL1 automatically.

Bit 1 OE2 Output Enable 2

If this bit is set, the OLVL2 will appear at Port 25 when a match between the FCR and the OCR2. When this bit is cleared, Port 25 will be I/O port. When set, it will be an output of OLVL2 automatically.



- Bit 2 OLVL2 Output Level 2 OLVL2 is transferred to Port 25 when a match is found between the FCR and the OCR2. If OE2, bit 5 of the TCSR2, is set, OLVL2 will appear at Port 25.
- Bit 3 EOCI2 Enable Output Compare Interrupt 2 When this bit is set, an internal interrupt (IRQ₃) is enabled for OCI2. When cleared, the interrupt is inhibited.
- Bit 4 Not Used
- Bit 5 OCF2 Output Compare Flag 2

This read-only bit is set when a match is found between the FCR and the OCR2. It is cleared by writing to the OCR2 (\$0019 or \$001A) followed by reading the TCSR2.

- Bit 6 OCF1 Output Compare Flag 1
- Bit 7 ICF Input Capture Flag OCF1 and ICF addresses are partially decoded. CPU read of the TCSR1/TCSR2 makes it possible to read OCF1 and ICF into bit 6 and bit 7.

Both the TCSR1 and TCSR2 will be cleared by reset.

- (Note) If OE1 or OE2 is set before the first output compare match is found after reset, Port 21 and Port 25 will output "0" respectively.
- (Note) Because the set condition of ICF precedes its reset condition, ICF is not cleared when the set condition and the reset condition occur simultaneously. The same phenomenon applies to OCF1, OCF2 or TOF respectively.

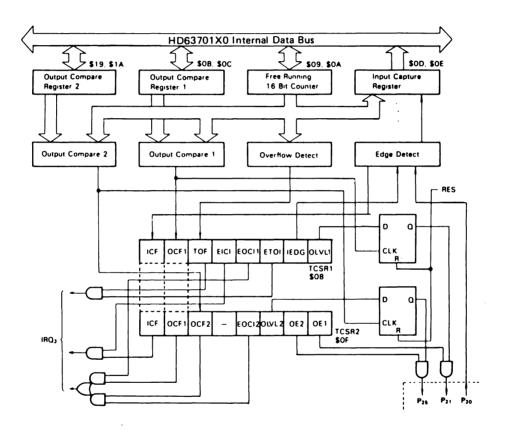


Figure 22 Timer 1 Block Diagram

TIMER 2

In addition to the timer 1, the HD63701X0 provides an 8-bit reloadable timer, which is capable of counting the external event. This timer 2 contains a timer output, so the MCU can generate three independent waveforms. (refer to Fig. 23.)

The timer 2 is configured as follows: Control/Status Register 3 (7 bit) 8-bit Up Counter Time Constant Register (8 bit)

• Timer 2 Up Counter (T2CNT) (\$001D)

This is an 8-bit up counter which is incremented by the clock controlled by CKS0 and CKS1 of the TCSR3. The T2CNT is always readable without affecting itself. In addition, any value can be written to the T2CNT by software even during counting.

The counter is cleared when a match is found between the T2CNT and the TCONR or by reset.

A write to the T2CNT at the clear cycle does not reset it but

put the data to it.

• Time Constant Register (TCONR) (\$001C)

The Timer Constant Register is an 8-bit write only register. It is always compared with the T2CNT.

When a match has been found, counter match flag (CMF) of the Timer Control/Status Register 3 (TCSR3) is set and the value selected by TOS0 and TOS1 of the TCSR3 will appear at Port 26. When CMF is set, the FCR will be cleared simultaneously and then a counting starts from \$00. This enables regular interrupts and waveform outputs without any software support. The TCONR is set to "\$FF" by reset.

• Timer Control/Status Register 3 (TCSR3) (\$001B)

The Timer Control/Status Register 3 is a 7-bit register. All bits are readable while 6 bits except for CMF can be written.



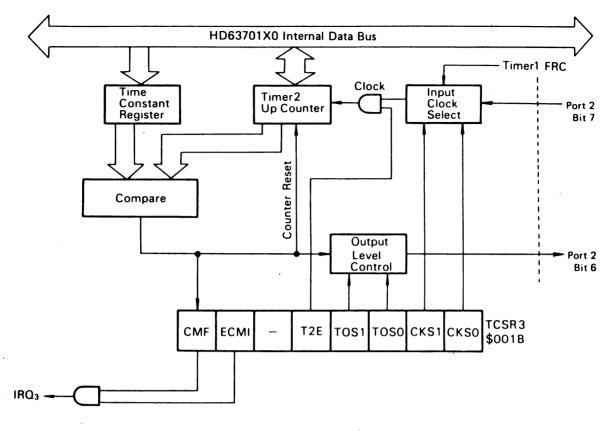
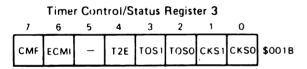


Figure 23 Timer 2 Block Diagram

The followings are each bit descriptions.



Bit 0 CKS0 Input Clock Select 0

Bit 1

CKS1 Input Clock Select 1 An input clock to the T2CNT is selected by these bits as shown in Table 7. When an external clock is selected, Port 27 will be an input automatically. The positive edge of the external clock increments the T2CNT. The maximum external clock is half of the system clock frequency.

Table 7	Input (Clock	Select
---------	---------	-------	--------

CKS1	CKS0	Input Clock to the Counter
0	0	E clock
0	1	E clock/8*
1	0	E clock/128*
1	1.	External clock

These clocks come from the FRC of the timer 1. If one of these clocks is selected as an input clock to the up counter, a write to the FRC of the timer 1 should be inhibited.

- Bit 2 TOSO Timer Output Select 0
- Bit 3 TOS1 Timer Output Select 1 When a match is found between the T2CNT and the TCONR, timer 2 output selected by these bits shown in Table 8 will appear at Port 26. When both TOS0 and TOS1 are cleared, Port 26 will be an I/O port.

Table 8 Timer 2 Output Select

TOS1	TOS0	Timer Output
0	0	Timer Output Inhibited
0	1	Toggle Output*
1	0	Output "0"
1	1	Output "1"

 When a match is found between the T2CNT and the TCONR, timer 2 output level is reversed. This leads to production of a square wave with 50% duty to the external without any software support.

Bit 4 T2E Timer 2 Enable Bit

When this bit is cleared, the T2CNT will stop. When set, a clock selected by CKS1 and CKS0 (Table 7) provides to the T2CNT.

- (Note) P_{26} is "0" when T2E is cleared and P_{26} is configured as an output by TOS1 or TOS0. It also is "0" when T2E is set and P_{26} is configured as an output before the first counter match.
- Bit 5 Not Used
- Bit 6 ECMI Enable Counter Match Interrupt

Bit 7

When this bit is set, an internal interrupt (IRQ_3) is enabled for CMI. When cleared, the interrupt is inhibited. CMF Counter Match Flag

This read only bit is set when a match is found between the T2CNT and the TCONR. It is cleared by writing "0". (It cannot be written "1" by software).

Each bit of the TCSR3 is cleared by reset.

SERIAL COMMUNICATION INTERFACE (SCI)

The HD63701X0 SCI provides two operation modes; one is an asynchronous mode by the NRZ format and the other is a clocked synchronous mode to transfer data synchronizing with the serial clock.

The serial interface is configured as follows:

- · Transmit/Receive Control and Status Register (TRCSR)
- Rate/Mode Control Register (RMCR)
- Receive Data Register (RDR)
- · Receive Data Shift Register (RDSR)
- Transmit Data Register (TDR)
- Transmit Data Shift Register (TDSR)

The SCI is initialized by software. The procedure is usually as follows:

- 1) Write a operation mode into each corresponding control bit of the RMCR.
- 2) Write a operation mode into each corresponding control bit of the TRCSR.

When setting the baud rate and operation mode, TE and RE should be "0". When TE and RE is set again, more than 1 bit cycle of the current baud rate is necessary. If set in less than 1 bit cycle, the SCI cannot be initialized occasionally.

• Asynchronous Mode

An asynchronous mode contains the following two data formats:

- 1 Start Bit + 8 Bit Data + 1 Stop Bit; 8 Bit Data Format 1 Start Bit + 9 Bit Data + 1 Stop Bit; 9 Bit Data Format
- In 9 Bit Data Format, if the 9th bit is "1", the format of
 - 1 Start Bit + 8 Bit Data + 2 Stop Bit

The SCI is initialized by writing desirable control bytes to the RMCR and then to the TRCSR.

The transmit operation is enabled by TE in the TRCSR. When TE is set, the output of the TDSR is connected to P_{24} which will be configured as an output regardless of the DDR, and then the serial output is initiated by transmitting to a 10-bit preamble of "1" in the 8 Bit Data Format or an 11-bit preamble of "1" in the 9 Bit Data Format. Following the preamble, the internal synchronization is established and the transmitter section is ready for operation.

At this point one of two situation exist:

- 1) If the TDR is empty (TDRE=1), a continuous string of ones will be sent indicating an idle line.
- If a byte has been written to the TDR (TDRE=0), it is transferred to the TDSR, TDRE will be set and transmission will begin.

During the transfer itself, the start bit (0) is first transmitted. Then the 8 data bits or the 9 data bits (beginning with bit 0) followed by the stop bit (1) are transmitted. When the TDR has been emptied, TDRE is set.

If the MCU fails to respond to the flag within the proper time, (TDRE is still set when the next normal transfer from the TDR to the TDSR should occure) then a "1" will be sent (instead of a "0") at start bit time, followed by more 1's until more data is supplied to the TDR. No 0's will be sent while TDRE remains as "1".

The receive operation is enabled by RE which configures P_{23} . The receive operation is controlled by the contents of the TRCSR and the RMCR. The receiver bit interval is divided into 8 sub-intervals for internal synchronization. The received bit stream is synchronized by the first "0" (space) encountered. The approximate center of each bit time is strobed during the next 10 bits.

If the tenth bit is not a "1" (stop bit), a framing error is assumed and ORFE is set. If the tenth bit is a "1", the data is transferred to the RDR and interrupt flag RDRF is set. If RDRF is still set at the next tenth bit time, ORFE will be set, indicating an over-run has occurred. When the CPU responds to either flag

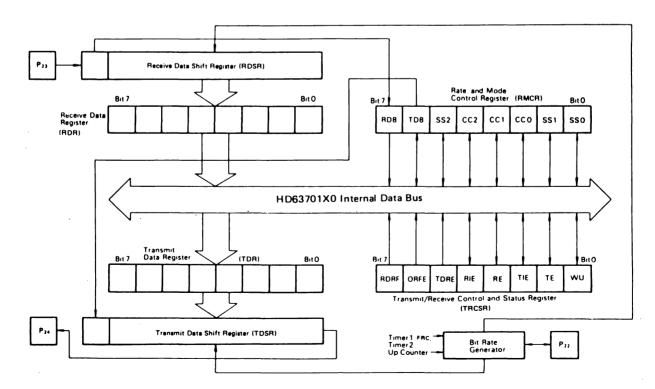


Figure 24 Serial Communication Interface Block Diagram



(RDRF or ORFE) by reading the TRCSR followed by reading the RDR, RDRF (or ORFE) will be cleared.

(Note) Clock Source in Asynchronous Mode

When using an internal clock for the SCI, the following requirements are applicable:

- Set CC1 and CC0 to "1" and "0" respectively.
- A clock is generated regardless of the value of TE, RE.
- The maximum clock rate is E + 16.
- The output clock is the same as the bit rate.

When using an external clock for the SCI, the following requirements are applicable:

- Set CC1 and CC0 in the RMCR to "1" and "1" respectively.
- The external clock should be set 16 times the desired baud rate.
- the maximum clock frequency is the same as the system clock.

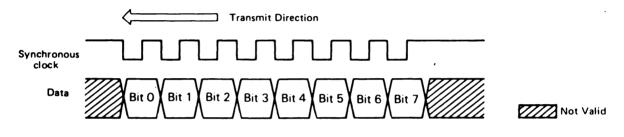
Clocked Synchronous Mode

In the clocked synchronous mode, the transmit operation is synchronized with the clock pulse. In the clocked synchronous mode an SCI clock I/O pin is only P_{22} , so the receive and transmit operation cannot be simultaneously enabled. Therefore, TE and RE should not be set simultaneously. Fig. 25 gives a synchronous clock and a data format in the clocked synchronous mode.

The transmit operation is enabled by TE in the TRCSR P_{24} is configured as an output regardless of the value of the corresponding DDR.

Both the RMCR and TRCSR should be set in the desirable operating conditions for data transmit.

If the user wishes to provide an external clock, the data bits (beginning with bit 0) are transmitted from P_{24} , synchronizing with 8 clock pulses supplied to P_{22} , when TDRE is "0". TDRE is set when the TDSR is "empty". More the 9th clock pulse is ignored.



Transmit data is sent between the negative edge of a synchronous clock and the next negative edge.

· Receive data is latched at the positive edge.



The receive operation is enabled by RE. P_{22} is configured as an input for the 8 bit external clock and P_{23} is configured as an input for the receive data. The operating mode of data receive is decided by the TRCSR and the RMCR.

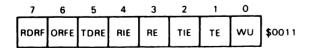
If the external clock is provided, RE should be set when P_{22} is "High". The receive data is transferred to the RDSR by this clock, and RDRF is set. More the 9th clock pulse are ignored. When RDRF is cleared by reading the RDR, the MCU starts receiving the next data.

RDRF, therefore, should be cleared with P_{22} "High". When the first byte data is received, RDRF is set. After the second byte, the receive operation is enabled by clearing RDRF.

Transmit/Receive Control and Status Register (TRCSR) (\$0011)

The TRCSR is an 8 bit register which is readable. Bits 0 to 4 are also writable. This register is initialized to \$20 by reset. Each bit functions as follows.





Bit 0 WU Wake-up

In a typical multi-processor configuration, the software protocol will usually identify the address at the beginning of the message. In order to permit uninterested MCU's to ignore the remaining message, a wake-up function is available. By this, uninterested MCU can inhibit all further receive processing till the next message starts.

Then wake-up function is triggered by consecutive 1's with 1 frame length (10 bits for the 8-bit data format, or 11 bits for the 9-bit data format). The software protocol should provide the idle time between messages.

By setting this bit, the MCU stops data receive till the next message. The receive of consecutive "1" with one frame length wakes up and clears this bit and then the MCU restarts the receive operation. However, the RE flag should be set before setting this bit. In the clocked synchronous mode WU is not available, so this bit should not be set.

Bit 1 TE Transmit Enable

When this bit is set, transmit data will appear at P_{24} after one frame preamble in asynchronous mode, while in clocked synchronous mode appear immediately. This is executed regardless of the value of the corresponding DDR. When TE is cleared, the serial I/O doesn't affect P_{24} .

Bit 2 TIE Transmit Interrupt Enable

When this bit is set, an internal interrupt (IRQ_3) is enabled when TDRE (bit 5) is set. When cleared, the interrupt is inhibited.

Bit 3 RE Receive Enable

When set, P_{23} is configured as an input for the receive operation regardless of the value of the DDR. When RE is cleared, the serial I/O doesn't affect P_{23} .

- Bit 4 RIE Receive Interrupt Enable
 - When this bit is set, an internal interrupt, IRQ_3 is enabled when RDRF (bit 7) or ORFE (bit 6) is set. When cleared, the interrupt is inhibited.

Bit 5 TDRE Transmit Data Register Empty



TDRE is set when the TDR is transferred to the TDSR in the asynchronous mode, while it is set when the TDSR is "empty" in clocked synchronous mode. This bit is cleared by reading the TRCSR and writing the new transmit data to the TDR. TDRE is set by reset.

- (Note) TE should be set before clearing TDRE.
- Bit 6 ORFE Overrun Framing Error

ORFE is set when an overrun or a framing error is occured (during data receive only). An overrun error occurs when a new receive data is ready to be transferred to the RDR with RDRF still set. A framing error occurs when a stop bit is "0". But in clocked synchronous mode, this bit is not affected. This bit is cleared when reading the TRCSR, then the RDR, or by reset.

Bit 7 RDRF Receive Data Register Full

RDRF is set when the RDSR is transferred to the RDR. Cleared when reading the TRCSR, then the RDR, or by reset.

(Note) When a few bits are set between bit 5 to bit 7 in the TRCSR, a read of the TRCSR is sufficient for clearing those bits. It is not necessary to read the TRCSR every-time to clear each bit.

Rate/Mode Control Register (RMCR)

The RMCR controls the followings:

Baud Rate
 Data Format
 Clock Source
 P₂₂ Function

In addition, if 9-bit data format is set in the asynchronous mode, the 9th bit is put in this register. All bits are readable and writable except bit 7 (read only). This register is cleared by reset.

These bits select the baud rate when using the internal clock. Table 9 lists the available bit times and baud rates. The timer 1's FRC (SS2=0) and the timer 2's up counter (SS2=1) provide

Rate/Mode Control Register

	7	6	5	4	3	2	1	0	
	RD8	TD8	SS2	CC2	CC1	ссо	SSI	SSO	\$0010
E	Bit O Bit 1 Bit 5	S	50] 51 } 52 }	Spee	ed Sel	ect			

the internal clock for the SCI. When the source of the SCI internal clock is the timer 2's up counter, the desired baud rates may be selected by the TCONR shown in Table 10.

(Note) When operating the SCI with internal clock, do not write to the counter which is the source of the SCI clock.

 Bit 2
 CC0

 Bit 3
 CC1

 Bit 4
 CC2

These bits select the data format and the clock source (refer to Table 11).

• CC0, CC1 and CC2 are cleared and the MCU will be in the clocked synchronous mode (the external clock operation) by reset. Then P_{22} is forced to be configured as an input for the clock. If using P_{22} for an output, the DDR of port 2 should be set to "1" and CC1, CC0 must be set to "01".

			XTAL	2 4576MHz	4.0MHz	4 9152MHz
SS2	SS1	SS0	E	614 4kHz	1.0MHz	1 2288MHz
0	0	0	E÷16	s/38400Baud بر 26	16µs/62500Baud	13 µs/76800Baud
0	0	1	E÷128	208 µs/4800Baud	128, s/7812 5Baud	104 2 µs/9600Baud
0	1	0	E÷1024	1.67ms/600Baud	1 024ms/976 6Baud	833.3µs/1200Baud
0	1	1	E÷4096	6 67ms/150Baud	4 096ms/244 1Baud	3.333ms/300Baud
1	_			*	*	*

Table 9 SCI Bit Times and Rates

* When SS2 is "1", Timer 2 provides SCI clocks. The baud rate is shown as follows with the TCONR as N.

Baud Rate =
$$\frac{f}{32 (N+1)}$$

 $\begin{pmatrix} f : \text{ input clock frequency to the timer 2 counter} \\ N = 0 \sim 255 \end{cases}$

(2) Clocked Synchronous Mode *

(1) Asynchronous Mode

۰.

			XTAL	4 OMHz	6 OMHz	8 OMHz
SS2	SS1	SS0	E	1.0MHz	1 5MHz	2 OMHz
0	0	0	E ÷ 2	2µs/bit	1 33µs/bit	1 _μ s/bit
0	0	1	E÷16	16µs/bit	10 7µs/bit	8µs/bit
0	1	0	E÷128	128µs/bit	85.3µs/bit	64 _{/4} s/bit
0	1	1	E÷512	512 µs/bit	341 //s/bit	256µs/bit
1		-	-	* *	**	* *

* Bit rates in the case of internal clock operation. In the case of external clock operation, the external clock is operatable up to DC $\sim 1/2$ system clock.

** The bit rate is shown as follows with the TCONR as N.

Bit Rate (μ s/bit) = $\frac{4 (N+1)}{f}$ $\begin{pmatrix} f: \text{ input clock frequency to the} \\ \text{timer 2 counter} \\ N = 0 \sim 255 \end{pmatrix}$

XTAL Baud Rate (Baud)	2.4576MHz	3 6864MHz	4.0MHz	4.9152MHz	8.0MHz
110	21	32.	35.	43*	70*
150	127	191	207	255	51
300	63	95	103	127	207
600	31	47	51	63	103
1200	15	23	25	31	51
2400	7	11	12	15	25
4800	3	5		7	12
9600	1	2		3	
19200	0			1	-
38400				0	

Table 10 Baud Rate and Time Constant Register Example

*E/8 clock is provided to the timer 2's up counter.

.

CC2	CC1	CC0	Format	Mode	Clock Source	Port 2, Bit 2	Port 2, Bit 3	Port 2, Bit 4
0	0	0	8-bit data	Clocked Synchronous	External	Input	<u>ן</u>	
0	0	1	8-bit data	Asynchronous	Internal	Not Used**		
0	1	0	8-bit data	Asynchronous	Internal	Output*	When RE is "1", a serial input,	bit 3 is used for
0	1	1	8-bit data	Asynchronous	External	Input	a sonar input.	
1	0	0	8-bit data	Clocked Synchronous	Internal	Output		
1	0	1	9-bit data	Asynchronous	Internal	Not Used**		
1	1	0	9-bit data	Asynchronous	Internal	Output*	When TE is "1", I a serial output.	bit 4 is used for
1	1	1	9-bit data	Asynchronous	External	Input		

	Table 11	SCI Format and Clock Source Control
--	----------	-------------------------------------

* Clock output regardless of RE or TE in the TRCSR.

** Not used for the SCI.

Bit 6 TD8 Transmit Data Bit 8 When selecting the 9-bit data format in the asynchronous mode, this bit is transmitted as the 9th data.

Bit 7 RD8 Receive Data Bit 8 When selecting the 9-bit data format in the asynchronous mode, this bit stores the 9th bit data.

TIMER, SCI STATUS FLAG

Table 12 shows set and clear conditions of each status flag in the timer 1, the timer 2 and the SCI.

If the flag set and clear conditions occur at the same time, the

flag of the Timer 1 and the Timer 2 will be set, and the SCI cleared. Therefore the OCF1 and OCF2 of the Timer 1 may not be cleared correctly because set signal is generated periodically whenever the OCR matches the FRC. In order to clear these flags correctly, the match should be prohibited during the period between reading the TSCR and writing the OCR. For instance, these flags will be cleared correctly if the TCSR is read and the OCR is written continuously soon after matching the value of the OCR and the FCR.

Refer to "APPLICATION NOTES-Cautions for OCF clearing in the TCSR of the Timer 1" for detail.

		Set Condition	Reset Condition
	ICF	FRC \rightarrow ICR by edge input to P ₂₀ .	1. Read the TCSR1 or TCSR2 then ICRH, when ICF=1
			2. RES=0
	OCF1	OCR1=FRC	1. Read the TCSR1 or TCSR2 then write to the OCR1H or OCR1L, when OCF1=1
Timer			2. RES=0
1	OCF2	OCR2=FRC	 Read the TCSR2 then write to the OCR2H or OCR2L, when OCF2=1 RES=0
	TOF	FRC=\$FFFF+1 cycle	1. Read the TCSR1 then FRCH, when TOF=1 2. RES=0
Timer 2	CMF	T2CNT=TCONR	 Write "0" to CMF, when CMF = 1 RES=0
	RDRF	Receive Shift Register → RDR	 Read the TRCSR then RDR, when RDRF=1 RES=0
SCI	ORFE	 Framing Error (Asynchronous Mode) Stop Bit = 0 Overrun Error (Asynchronous Mode) Receive Shift Register → RDR when RDRF=1 	 Read the TRCSR then RDR, when ORFE = 1 RES=0
301	TDRE	 Asynchronous Mode TDR → Transmit Shift Register Clocked Synchronous Mode Transmit Shift Register is "empty" RES=0 	Read the TRCSR then write to the TDR, when TDRE=1 (Note) Clear TDRE after setting TE.

Table 12 Timer 1, Timer 2 and SCI Status Flag

(Note) 1. →; transfer

2. For example; "ICRH" means High byte of ICR.



■ LOW POWER DISSIPATION MODE

The HD63701X0 provides two low power dissipation modes; sleep and standby.

• Sleep Mode

The MCU will be in the sleep mode when SLP instruction is executed. In the sleep mode, the CPU stops and the registers' contents are retained. While the peripherals such as timers, SCI etc. continue their functions. The power dissipation of the sleepcondition is one fifth that of the operating condition.

The MCU returns from this mode by an interrupt, \overline{RES} or STBY; it will be reset by \overline{RES} and the standby mode by STBY. When the CPU responds to an interrupt request, it cancels the sleep mode, returns to the operation mode and branches to the interrupt routine. When the CPU masks this interrupt, it cancels the sleep mode and executes the next instruction. However, for example if the timer 1 or 2 prohibits a timer interrupt request.

This sleep mode is effective to reduce the power dissipation for a system with no need of the HD63701X0's consecutive op-

eration.

Standby Mode

In MCU mode, the HD63701X0 stops and reset with STBY "low". In this mode, the power dissipation is reduced conspicuously. All pins except for the power supply, STBY and XTAL are detached from the MCU internally and will be the high impedance state.

While the contents of RAM is retained. The MCU returns from this mode by reset. The followings are typical usage of this mode.

Save the CPU information and SP contents on RAM by \overline{NMI} . Then disable the RAME bit of the RAM control register and set the STBY PWR bit to go to the standby mode. If the STBY PWR bit is still set at reset, that indicates the power is supplied to the MCU and RAM contents are retained properly. So system can restore itself by returning their pre-standby informations to the SP and the CPU. Fig. 26 depicts the timing at each pin with this example.

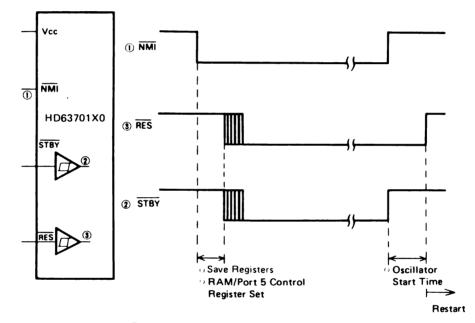


Figure 26 Standby Mode Timing

■ TRAP FUNCTION

The CPU generates an interrupt with the highest priority (TRAP) when fetching an undefined instruction or an instruction from non-memory space. The TRAP prevents the system-burst caused by noise or a program error.

• Op Code Error

When fetching an undefined op code, the CPU saves CPU registers as well as a normal interrupt and branches to the TRAP (\$FFEE, \$FFEF). This provides the priority next to reset.

Address Error

When an instruction fetch is made excluding internal PROM, RAM and external memory area, the MCU generates an interrupt as well as an op code error. But on the system with no memory in its external memory area, this error processing is not applicable if an instruction fetch is made from the external nonmemory area. Table 13 provides addresses where an address error occurs to each mode.

This processing is available only for an instruction fetch and is not applicable to the access of normal data read/write.

Table 13 Addresses Applicable to Address Errors

Mode	1	2	. 3
	\$0000	\$0000	\$0000
	2	2	1
Address	\$001F	\$001F	\$003F
			\$0100
			1
			\$EFFF

(Note) The TRAP interrupt provides a retry function differently from other interrupts. This is a program flow return to the address where the TRAP occurs when a sequence returns to a main routine from the TRAP interrupt routine by RTI. The retry can prevent the system burst caused by noise etc.

> However, if another TRAP occurs, the program repeats the TRAP interrupt forever, so the consideration is necessary in programming.



INSTRUCTION SET

The HD63701X0 provides object code upward compatible with the HD6801 to utilize all instruction set of the HMCS6800. It also reduces the execution times of key instructions for throughout improvement.

Bit manipulation instruction, change instruction of the index register and accumulator and sleep instruction are also added. The followings are explained here.

- CPU Programming Model (refer to Fig. 27)
- · Addressing Mode
- Accumulator and Memory Manipulation Instruction (refer to Table 14)
- New Instruction
- Index Register and Stack Manipulation Instruction (refer to Table 15)
- · Jump and Branch Instruction (refer to Table 16)
- Condition Code Register Manipulation
- (refer to Table 17)
- · Op Code Map (refer to Table 18)

Programming Model

Fig. 27 depicts the HD63701X0 programming model. The double accumulator D consists of accumulator A and B, so when using the accumulator D, the contents of A and B are destroyed.

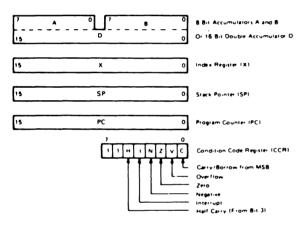


Figure 27 CPU Programming Model

• CPU Addressing Mode

The HD63701X0 provides 7 addressing modes. The addressing mode is decided by an instruction type and code. Table 14 through 18 show addressing modes of each instruction with the execution times counted by the machine cycle.

When the clock frequency is 4MHz, the machine cycle time becomes microseconds directly.

Accumulator (ACCX) Addressing

Only an accumulator is addressed and the accumulator ${\bf A}$ or ${\bf B}$ is selected. This is a one-byte instruction.

Immediate Addressing

This addressing locates a data in the second byte of an instruction. However, LDS and LDX locate a data in the second and third byte exceptionally. This addressing is a 2 or 3-byte instruction.

Direct Addressing

In this addressing mode, the second byte of an instruction shows the address where a data is stored. 256 bytes (\$0 through \$255) can be addressed directly. Execution times can be reduced by storing data in this area so it is recommended to make it RAM for users' data area in configurating a system. This is a 2byte instruction, while 3 byte with regard to AIM, OIM, EIM and TIM.

Extended Addressing

In this mode, the second byte shows the upper 8 bit of the data stored address and the third byte the lower 8 bit. This indicates the absolute address of 3 byte instruction in the memory. Indexed Addressing

The second byte of an instruction and the lower 8 bit of the index register are added in this mode. As for AIM, OIM, EIM and TIM, the third byte of an instruction and the lower 8 bits of the index register are added.

This carry is added to the upper 8 bit of the index register and the result is used for addressing the memory. The modified address is retained in the temporary address register, so the contents of the index register doesn't change. This is a 2-byte instruction except AIM, OIM, EIM and TIM (3-byte instruction). Implied Addressing

An instruction itself specifies the address. That is, the instruction addresses a stack pointer, index register etc. This is a onebyte instruction.

Relative Addressing

The second byte of an instruction and the lower 8 bits of the program counter are added. The carry or borrow is added to the upper 8 bit. So addressing from -126 to +129 byte of the current instruction is enabled. This is a 2-byte instruction. (Note) CLI, SEI Instructions and Interrupt Operation

When accepting the IRQ at a preset timing with the help of CLI and SEI instructions, more than 2 cycles are necessary between the CLI and SEI instructions. For example, the following program (a) (b) don't accept the IRQ but (c) accepts it.

•	•	•
•	•	•
•	•	•
•	•	CLI
CLI	CLI	NOP
SEI	NOP	NOP
•	SEI	SEI
•	•	•
•	•	•
•	•	•
•	•	•
(a)	(Ь)	(c)

The same thing can be said to the TAP instruction instead of the CLI and SEI instructions.



							Add	Iressi	ng N	Aod	es							Condition Code Register										
Operations	Mnemonic	IM	MED	5	DIF	EC	т	IN	DE>		EXT	EN	D	IMP	LIE	D	Boolean/ Arithmetic Operation	5			2	1	0					
		OP	~		OP	~	#	OP	~	#	OP	~	#	OP	~	#		н	ī	N	z	v	c					
Add	ADDA	88	2	2	98	3	2	AB	4	2	88	4	3				A + M + A	1	•	1	1	:	1.					
	ADDB	СВ	2	2	DB	3	2	EB	4	2	FB	4	3	-			B + M + B	1	•	:	1	1	$\frac{1}{1}$					
Add Double	ADDD	C3	3	3	03	4	2	E 3	5	2	F 3	5	3				A B + M M + 1 • A B	•	•	1	:	1	1:					
Add Accumulators	ABA		 	-		-	-		-	•		_	-	18	1	1	A + B + A	1	•	1	:	1						
Add With Carry	ADCA	89	2	2	99	3	2	Α9	4	2	89	4	3			-	A + M + C → A	1	•	;	1	1	1:					
	ADCB	C9	2	2	D9	3	2	E9	4	2	F9	4	3				B + M + C → B	1	•	1	1	i						
AND	ANDA	84	2	2	94	3	2	A4	4	2	84	4	3				A·M · A	•	•	1	1	R	•					
	ANDB	C4	2	2	D4	3	2	E4	4	2	F4	4	3				B·M → B	•	•	1	1	R	1.					
Bit Test	BITA	85	2	2	95	3	2	A5	4	2	85	4	3				A·M	•	•	1	1	R	•					
	BITB	C5	2	2	D5	3	2	E5	4	2	F5	4	3				B·M	•	•	1	1	R	1.					
Clear	CLR		1		<u> </u>		\square	6F	5	2	7F	5	3		-	1-	00 - M	•	•	R	s	R	R					
	CLRA	1	\uparrow	<u>† </u>	1									4F	1	1	00 · A	•	•	R	s	R	R					
ł	CLRB	1	t	1		-								5F	1	1	00 · B	•	•	R	s	R	R					
Compare	СМРА	81	2	2	91	3	2	AI	4	2	81	4	3				A - M	•	•	1	1	1:	1:					
	СМРВ	CI	2	+	DI	3	2	E1	4	2	F1	4	3				B - M	•	•	1	1	1	1					
Compare Accumulators	СВА		T											11	1	1	A - B	•	•	1	:	1	1					
Complement, 1's	COM		1					63	6	2	73	6	3		-	1	м • м	•		1	1	R	s					
	COMA		1-	╞	†		t							43	1	1	Ā → A	•		:	1	R	15					
	СОМВ		\uparrow				F							53	1	1	8 → 8	•	•	1	1	R	1					
Complement, 2's	NEG	1	t	1				60	6	2	70	6	3			t	00 - M • M	•	•	:	11	Ű,	2					
(Negate)	NEGA		1	1									-	40	1	1	00 - A → A	•	•	1	1	11	1					
-	NEGB		Γ.	Γ			Γ							50	1	1	00 - B → B	•	•	1	:	6,						
Decimal Adjust, A	DAA		Γ			Ι								19	2	1	Converts binary add of BCD characters into BCD format	•	•	:	:	1	.1					
Decrement	DEC		Γ	Γ			Γ	6A	6	2	7A	6	3				M - 1 · M	•	•	:	1	.4,	•					
	DECA													4A	1	1	A - 1 • A	•	•	1	1	(4)	, •					
	DECB													5A	1	1	B - 1 → B	•	•	:	1	•4,	•					
Exclusive OR	EORA	88	2	2	98	3	2	A8	4	2	88	4	3				A () M → A	•	•	1	:	R	T					
	EORB	C8	2	2	D8	3	2	E8	4	2	F8	4	3				B (•) M + B	•	•	:	1	R	•					
Increment	INC		Γ				Γ	6C	6	2	7C	6	3				M + 1 + M	•	•	1	1	(5)) [•					
	INCA													4C	1	1	A + 1 + A	•	•	1	1	15						
	INCB		T											5C	1	1	B + 1 → B	•	•	1	1	5	•					
Load	LDAA	86	2	2	96	3	2	A6	4	2	B6	4	3				M -+ A	•	•	1	1	R	•					
Accumulator	LDAB	C6	2	2	D6	3	2	E6	4	2	F6	4	3				M → B	•	•	1	1	R	1					
Load Double Accumulator	LDD	сс	3	3	DC	4	2	€C	5	2	FC	5	3				M + 1 + B, M + A	•	•	1	1	R						
Multiply Unsigned	MUL													30	7	1	A × B • A . B	•	•	•		+	+					
OR, Inclusive	ORAA	8A	2	2	9A	3		AA	_		8A	-					A + M → A	•	•	_	1	_	_					
	ORAB	CA	2	2	DA	3	2	EA	4	2	FA	4	3	-			8 + M · B	•	•	1	-	R	_					
Push Data	PSHA		T											36	-	1		•	•	+	+	•	+					
	PSHB							\bot		1_				37	4	1	$B \rightarrow Msp, SP - 1 \rightarrow SP$	•	•	•	•	•	ľ					
Pull Data	PULA												\downarrow	32	3	1		•	•	•	•	•	ľ					
	PULB		1-	_		\downarrow			1					33	3	1	$SP + 1 \rightarrow SP, Msp \rightarrow B$	•	•	•	+	+-	+					
Rotate Left	ROL	ļ	\downarrow		L			69	6	2	79	6	3	 			M, [•	•	1	+	-	-					
	ROLA													49		1	C bi bi	•	•	1		-	-					
	0010	T	T	T			—			1	1			59	1	Tī	∃ 8 ¹ ⊂ 87 = ∞	•		1	11	6	D					
	ROLB	_		_	_		-	-	-	-		-	+		-	-		-	-	+	-							
Rotate Right	ROR		╞	\perp		t	t	66	6	2	76	6	3			1,		ŀ	•	1	_	-						

Table 14 Accumulator, Memory Manipulation Instructions

(Note) Condition Code Register will be explained in Note of Table 17.

(continued)



							Add	Iressi	ng P	Mod	les						_	C	ono I		on (iste		•
Operations	Mnemonic	IM	MEI	2	DIF	EC	T	IN	DE	<	EX.	TEN	D	IM	PLIE	ED	Boolean/ Arithmetic Operation	5	4	3	2	1	0
		OP	~	#	OP	~	#	OP	~	#	OP	~	*	OP	~	#		н	۱	N	z	v	6
Shift Left	ASL		Γ				Γ	68	6	2	78	6	3			Γ	M,	•	٠	1	:	6	1
Arithmetic	ASLA													48	1	1		•	•	:	1	6	1
	ASLB													58	1	1	в С 67 60	•	•	:	1	6	1
Double Shift Left, Arithmetic	ASLD													05	1	1		•	•	1	:	6	1
Shift Right	ASR							67	6	2	77	6	3				M)	•	•	:	:	6	1
Arithmetic	ASRA													47	1	1		٠	•	1		6	1
	ASRB													57	1	1	в) ⁵⁷ 50 С	٠	٠	1	1	6	1
Shift Right	LSR							64	6	2	74	6	3				M)	•	•	R	1	6	
Logical	LSRA													44	1	1		•	•	R	:	6	I
	LSRB		Ι											54	1	1	8) 87 56 5	•	•	R	1	6	
Double Shift Right Logical	LSRD													04	1	 ,	0	•	•	R	1	6	
Store	STAA				97	3	2	A7	4	2	87	4	3				A → M	•	•	1	1	R	•
Accumulator	STAB				D7	3	2	E7	4	2	F7	4	3			Γ	B → M	•	•	1	1	R	•
Store Double Accumulator	STD				DD	4	2	ED	5	2	۶D	5	3				$ \begin{array}{c} A \rightarrow M \\ B \rightarrow M + 1 \end{array} $	•	•	:	:	R	ŀ
Subtract	SUBA	80	2	2	90	3	2	A0	4	2	во	4	3				$A - M \rightarrow A$	•	•	:	:	:	1
	SUBB	C0	2	2	DO	3	2	EO	4	2	FO	4	3				B - M → B	•	•	1	1	:	Ŀ
Double Subtract	SUBD	83	3	3	93	4	2	A3	5	2	B 3	5	3				A : B – M : M + 1 → A : B	•	•	:	1	1	
Subtract Accumulators	SBA													10	1	1	A - B → A	•	•	:	:	:	1
Subtract	SBCA	82	2	2	92	3	2	A2	4	2	B2	4	3				A – M – C → A	•	•	1	1	:	
With Carry	SBCB	C2	2	2	D2	3	2	E2	4	2	F2	4	3				B – M – C → B	•	•	1	1	1	L
Transfer	TAB													16	1	1	A → B	•	•	1	1	R	Ŀ
Accumulators	TBA		ļ					ļ				↓		17	1	1	B → A	•	•	1	1	R	Ŀ
Test Zero or	TST	↓	ļ					6D	4	2	7D	4	3				M - 00	•	•	1	1	R	Ľ
Minus	TSTA	┢	1											4D	1	1	A - 00	•	•	1	1	R	Ľ
	TSTB													5D	1	1	8 - 00	•	•	1	1	R	ľ
And Immediate	AIM	_	L		71	6	3	61	7	3	L		L				M·IMM→M	•	•	1	1	R	ŀ
OR Immediate	OIM				72	6	3	62	7	3							M+IMM →M	•	•	1	1	R	I
EOR Immediate	EIM				75	6	3	65	7	3							M⊕IMM →M	•	•	1	:	R	ŀ
Test Immediate	TIM			1	78	4	3	6B	5	3					[M-IMM	•	•	1	1	R	t

Table 14 Accumulator, Memory Manipulation Instructions

(Note) Condition Code Register will be explained in Note of Table 17.

Additional Instruction

In addition to the HD6801 instruction set, the HD63701X0 prepares the following new instructions.

AIM..... $(M) \cdot (IMM) \rightarrow (M)$

Executes "AND" operation to immediate data and the memory contents and stores its result in the memory.

$$OIM \dots (M) + (IMM) \rightarrow (M)$$

Executes "OR" operation to immediate data and the memory contents and stores its result in the memory.

$$EIM \dots (M) \oplus (IMM) \rightarrow (M)$$

Executes "EOR" operation to immediate data and the memory contents and stores its result in the memory.

$TIM \dots (M) \cdot (IMM)$

Executes "AND" operation to immediate data and changes the relative flag of the condition code register.

These area 3-byte instructions; the first byte is op code, the second immediate data and the third address modifier.

XGDX.... (ACCD) \leftrightarrow (IX)

Exchanges the contents of accumulator and the index register.

SLP

Goes to the sleep mode. Refer to "LOW POWER DIS-SIPATION MODE" for more details of the sleep mode.

							Ade	dress	ing	Mod	des						Boolean/	(òni I		on (ister		•
Pointer Operations	Mnemonic	IM	ME	D	DI	REC	т	IN	DE	×	EX.	TEN	D	IMP	LIE	D	Arithmetic Operation	5	4	3	2	1	0
		OP	[~	#	OP	~	#	OP	~	#	OP	~	*	OP	~	#		н	1	N	z	v	c
Compare Index Reg	CPX :	8C	3	3	9C	4	2	AC	5	2	BC	5	3				X - M M + 1	٠	•	:	:	:	:
Decrement Index Reg	DEX		Ι						Ι					09	1	1	$X - 1 \rightarrow X$	•	•	•	:	•	•
Decrement Stack Pntr	DES		I						Γ					34	1	1	SP – 1 → SP	•	•	•	•	•	•
Increment Index Reg	INX		Γ											08	1	1	X + 1 → X	٠	•	•	1	•	•
Increment Stack Pntr	INS													31	1	1	SP + 1 → SP	٠	•	•	•	•	•
Load Index Reg	LDX	CE	3	3	DE	4	2	EE	5	2	FE	5	3				$M \rightarrow X_{H_{i}} (M + 1) \rightarrow X_{L}$	٠	•	7	1	R	•
Load Stack Pntr	LDS	8E	3	3	9E	4	2	AE	5	2	BE	5	3				$M \rightarrow SP_{H}, (M+1) \rightarrow SP_{L}$	•	•	7	1	R	•
Store Index Reg	STX	Ι			DF	4	2	EF	5	2	FF	5	3				$X_H \rightarrow M, X_L \rightarrow (M + 1)$	٠	•	7	:	R	•
Store Stack Pntr	STS				9F	4	2	AF	5	2	BF	5	3		-		$SP_H \rightarrow M, SP_L \rightarrow (M+1)$	•	•	7	:	R	•
Index Reg → Stack Pntr	TXS		Ι	Γ										35	1	1	X – 1 → SP	٠	•	•	•	٠	•
Stack Pntr -> Index Reg	TSX													30	1	1	$SP + 1 \rightarrow X$	•	•	•	•	٠	•
Add	ABX		1	Γ	1	1	1	1	1					3A	1	1	B + X → X	•	•	•	•	٠	•
Push Data	PSHX								1					зc	5	1	X _L → M _{sp} , SP – 1 → SP	•	•	•	•	•	•
																	X _H → M _{sD} , SP = 1 → SP						
Pull Data	PULX		T	T	1	T	1		1				1	38	4	1	$SP + 1 \rightarrow SP, M_{SP} \rightarrow X_H$	•	•	•	•	•	•
													ł.				SP + 1 → SP, M _{BD} → XL						
Exchange	XGDX	1	T	1	<u> </u>	1	1		1	—				18	2	1	ACCD++IX	•	•	•	•	•	•

Table 15 Index Register, Stack Manipulation Instructions

(Note) Condition Code Register will be explained in Note of Table 17.

							Ad	dress	ing	Мо	des							6			on (iste		e
Operations	Mnemonic	REL	ATI	VE	DI	REC	т	IN	DE	x	EXT	EN	D	IMP	LIE	D	Branch Test	5	4	3	2	1	0
		OP	~	#	OP	~		OP	~	#	OP	~		OP	~	Ħ		н	1	N	Z	V	С
Branch Always	BRA	20	3	2													None	•	•	•	•	•	٠
Branch Never	BRN	21	3	2													None	•	•	•	•	•	•
Branch If Carry Clear	BCC	24	3	2													C = 0	•	•	•	•	•	٠
Branch If Carry Set	BCS	25	3	2													C = 1	•	٠	•	•	•	•
Branch If = Zero	BEQ	27	3	2													Z = 1	•	•	•	•	•	٠
Branch If > Zero	BGE	2C	3	2			Γ										N ⊕ V = 0	•	•	•	•	•	•
Branch If > Zero	BGT	2E	3	2		Ι				Γ							Z + (N (+ V) = 0	•	•	•	•	•	٠
Branch If Higher	вні	22	3	2			1				1						C + Z = 0	•	•	•	•	•	٠
Branch If < Zero	BLE	2F	3	2		Γ		Γ		Γ			Γ				Z + (N (+) V) = 1	•	•	•	•	•	•
Branch If Lower Or Same	BLS	23	3	2													C + Z = 1	•	•	•	•	•	•
Branch If < Zero	BLT	2D	3	2		Ι	Γ						Γ				N ⊕ V = 1	•	•	•	•	•	•
Branch If Minus	BMI	28	3	2				1		1							N = 1	•	•	•	•	•	•
Branch If Not Equal Zero	BNE	26	3	2													Z = 0	•	•	•	•	•	•
Branch If Overflow Clear	BVC	28	3	2													V = 0	•	•	•	•	•	•
Branch If Overflow Set	BVS	29	3	2		Γ											V = 1	•	•	•	•	•	•
Branch If Plus	BPL	2A	3	2				Ι			[I		N = 0	•	•	•	•	•	•
Branch To Subroutine	BSR	8D	5	2														•	•	•	•	•	•
Jump	JMP	1		1	1		1	6E	3	2	7E	3	3					•	•	•	•	•	•
Jump To Subroutine	JSR			Γ	9D	5	2	AD	5	2	BD	6	3				1	•	•	•	•	•	•
No Operation	NOP						Γ							01	1	۱	Advances Prog. Cntr. Only	•	•	•	•	•	•
Return From Interrupt	RTI			Γ		Γ								3B	10	1		-		- :	Ĩ.		
Return From Subroutine	RTS			Γ										39	5	1]	•	•	•	•	•	•
Software Interrupt	SWI			1										3F	12	1]	•	S	•	•	•	•
Wait for Interrupt*	WAI		Γ											3E	9	1		•	ŝ	•	•	•	•
Sleep	SLP		1	Г		T	T	T		Γ			Γ	14	4	1		•	•	•	•	•	•

Table 16 Jump, Branch Instruction

(Note) * WAI puts R/W high; Address Bus goes to FFFF; Data Bus goes to the three state. Condition Code Register will be explained in Note of Table 17.

		AddressingModes Mnemonic IMPLIED				Condition Code Register						
Operations	Mnemonic				Boolean Operation	5	4	3	2	1	0	
		OP	~	#		н	I	N	Z	V	С	
Clear Carry	CLC	0C	1	1	0 → C	•	•	•	•	•	R	
Clear Interrupt Mask	CLI	0E	1	1	0 → I	•	R	•	•	•	•	
Clear Overflow	CLV	0A	1	1	0 → V	•	•	•	•	R	•	
Set Carry	SEC	OD	1	1	1 → C	•	•	•	•	•	S	
Set Interrupt Mask	SEI	OF	1	1	1 → I	•	S	•	•	•	•	
Set Overflow	SEV	08	1	1	1 → V	•	•	•	•	S	•	
Accumulator A → CCR	ΤΑΡ	06	1	1				(0 -			
CCR → Accumulator A	TPA	07	1	1	CCR - A	•	•	•	•	•	•	

Table 17 Condition Code Register Manipulation Instructions

LEGEND

OP Operation Code (Hexadecimal)

- ~ Number of MCU Cycles
- M_{SP} Contents of memory location pointed to by Stack Pointer # Number of Program Bytes
- + Arithmetic Plus
- Arithmetic Minus
- Boolean AND
- + Boolean Inclusive OR
- Boolean Exclusive OR
- M Complement of M
- → Transfer into
- 0 Bit = Zero

CONDITION CODE SYMBOLS

- H Half-carry from bit 3 to bit 4
- I Interrupt mask
- N Negative (sign bit)
- Z Zero (byte)
- V Overflow, 2's complement
- C Carry/Borrow from/to bit 7
- R Reset Always
- S Set Always
- Set if true after test or clear
- Not Affected
- 00 Byte = Zero

(Note) Condition Code Register Notes: (Bit set if test is true and cleared otherwise)

- (i) (Bit V) Test: Result = 1000000?
- 2 (Bit C) Test: Result \$ 0000000?
- (i) (Bit C) Test: BCD Character of high-order byte greater than 10? (Not cleared if previously set)
- (4) (Bit V) Test: Operand = 10000000 prior to execution?
- (5 (Bit V) Test: Operand = 01111111 prior to execution?
- 6 (Bit V) Test: Set equal to NO C = 1 after the execution of instructions
- 7 (Bit N) Test: Result less than zero? (Bit 15=1)
- (8) (All Bit) Load Condition Code Register from Stack.
- (9) (Bit 1) Set when interrupt occurs. If previously set, a Non-Maskable Interrupt is required to exist the wait state.
- (10) (All Bit) Set according to the contents of Accumulator A.
- (ii) (Bit C) Result of Multiplication Bit 7=1? (ACCB)

OP						ACC	ACC		EXT		ACCA	or SP			ACCE	or X]
COD	E					A	A B IND DIR IMM DIR IND EXT					IMM	DIR	IND	EXT]		
H	ī	0000	0001	0010	0011	0100	0101	0110	0111	1000	1001	1010	1011	1100	1101	1110	1111]
LO	\searrow	0	1	2	3	4	5	6	7	8	9	•	8	С	D	Ε	F	
0000	0		SBA	BRA	TSX		N	EG					S	JB				0
0001	1	NOP	CBA	BRN	INS			A	M				CI	MP				1
0010	2			вні	PULA		OIM SBC								2			
0011	3			BLS	PULB		COM SUBD					8D			AD	DD		3
0100	4	LSRD		BCC	DES		LSR				AND							4
0101	5	ASLD		BCS	TXS		EIM						8	П				5
0110	6	TAP	TAB	BNE	PSHA		R	OR					L	A				6
0111	7	TPA	TBA	BEQ	PSHB		A	SR				STA				STA		7
1000	8	INX	XGDX	BVC	PULX			SL		EOR								8
1001	9	DEX	DAA	BVS	RTS		R	OL		ADC								9
1010	A	CLV	SLP	BPL	ABX		D	EC					0	RA				A
1011	В	SEV	ABA	BMI	RTI			Т	IM				A	DD				B
1100	С	CLC		BGE	PSHX		11	NC			C	РХ			L	D		С
1101	D	SEC		BLT	MUL		T	ST		BSR		JSR				STD		D
1110	Ε	СП		BGT	WAI	\leq		l l	MP	P LDS LDX					Ε			
1111	F	SEI		BLE	SWI		С	LR	_	STS STX						F		
		0	1	2	3	4	5	6	7	8	9	A	B	С	D	E	F	

UNDEFINED OP CODE

* Only each instructions of AIM, OIM, EIM, TIM



CPU OPERATION

• CPU Instruction Flow

When operating, the CPU fetches an instruction from a memory and executes the required functions. This sequence starts after the reset release and repeats itself limitlessly if not affected by a special instruction or a control signal. SWI, RTI, WAI and SLP instructions are to change this operation, while \overline{NMI} , \overline{IRQ}_1 , \overline{IRQ}_2 , IRQ_3 , \overline{HALT} and \overline{STBY} are to control it. Fig. 28 gives the CPU mode shift and Fig. 29 the CPU system flow-chart. Table 19 shows the CPU operating states and port states.

• Operation at Each Instruction Cycle

Table 20 provides the operation at each instruction cycle. By the pipeline control of the HD63701X0, MULT, PUL, DAA and XGDX instructions etc. prefetch the next instruction. So attention is necessary to the counting of the instruction cycles because it is different from the existent one ----- op code fetch to the next instruction op code.

Table 10	CPU Operation State and Port State	
	CFU Operation State and Fort State	

Port	Mode	Reset	STBY	HALT ***	Sleep
Port 1	Mode 1, 2	н	т	Т	н
$(A_0 \sim A_7)$	Mode 3	Т	1 '		Keep
Port 2	Mode 1, 2	т	т	Keep	Кеер
POR 2	Mode 3				Keep
Port 3	Mode 1,2	т	т	Т	т
$(D_o \sim D_\gamma)$	Mode 3				Keep
Port 4	Mode 1, 2	н	т	Т	н
$(A_{a} \sim A_{15})$	Mode 3	Т			Keep
Port 5	Mode 1, 2	т	т	Τ.	т
FUR 5	Mode 3	<u> </u>	ļ		
Port 6	Mode 1, 2	т	т	Кеер	Кеер
FUILO	Mode 3				Keep
Port 7	Mode 1, 2	•	т	••	•
Port 7	Mode 3	Т]		Кеер

H; High, L; Low, T; High Impedance

• RD, WR, R/W, LIR=H, BA=L

•• RD, WR, R/W=T, LIR, BA=H

*** HALT is unacceptable in mode 3.

•••• E pin goes to high impedance state.

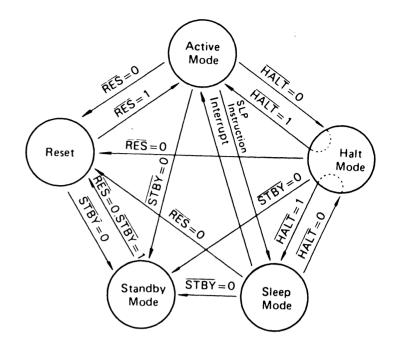


Figure 28 CPU Operation Mode Transition



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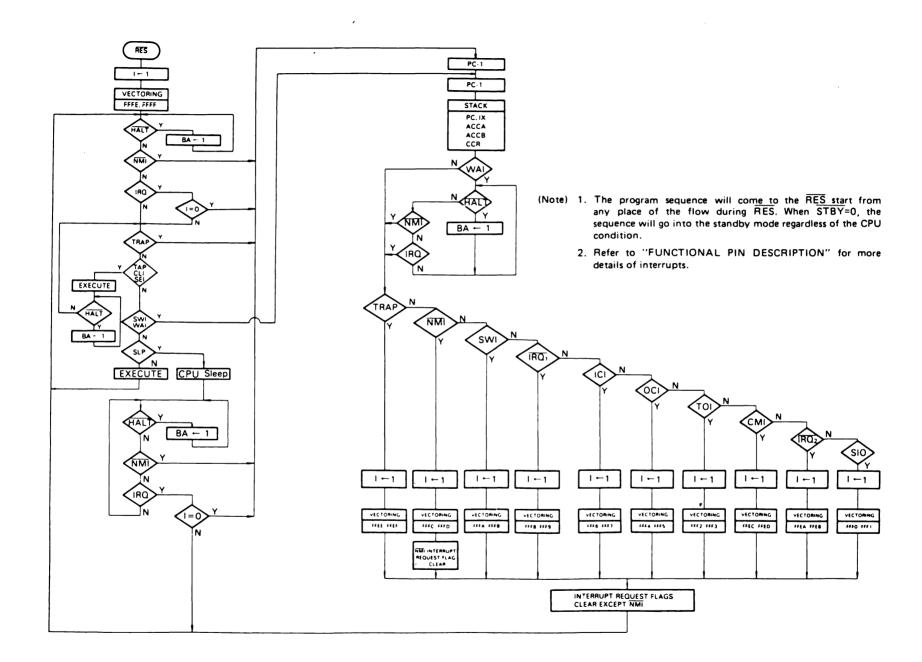


Figure 29 HD63701X0 System Flow Chart

	s Mode &	Cycles	Cycle	Address Bus	₽∕₩	RD	WR	LIR	Data Bus
MMEDIA			<u> </u>		-				
ADC	ADD	T	1	Op Code Address + 1	1 1	0	1	1	Operand Data
AND	BIT	1	2	Op Code Address + 2	1	õ	1	0	Next Op Code
СМР	EOR	2				-		-	
LDA	ORA		1						
SBC	SUB		1 1						
ADDD	СРХ	<u> </u>	1	Op Code Address + 1	1	0	1	1	Operand Data (MSB)
LDD	LDS	3	2	Op Code Address + 2	1	0	1	1	Operand Data (LSB)
LDX	SUBD	1	3	Op Code Address + 3	1	0	1	0	Next Op Code
DIRECT									
ADC	ADD	1	1 1	Op Code Address + 1	1 1	0	1		Address of Operand (LSB
AND	BIT		2	Address of Operand		o	1	1	Operand Data
CMP	EOR	3	3	Op Code Address + 2		õ	1	o	Next Op Code
LDA	ORA	Ĭ	l ŭ l			Ŭ		Ŭ	
SBC	SUB								
STA				Op Code Address + 1	$+_{1}$	0	1		Destination Address
		3	2	Destination Address	0		0	1	Accumulator Data
		-	3	Op Code Address + 2	1	Ó	1	0	Next Op Code
ADDD	СРХ		1	Op Code Address + 1	1	0	1	1	Address of Operand (LSB
LDD	LDS		2	Address of Operand	1	0	1	i	Operand Data (MSB)
LDX	SUBD	4	3	Address of Operand + 1	1	0	1	1	Operand Data (LSB)
-			4	Op Code Address + 2	1	0	1	0	Next Op Code
STD	STS		1	Op Code Address + 1	1	0	1	1	Destination Address (LSB
STX			2	Destination Address	0	1	0	1	Register Data (MSB)
		4	3	Destination Address + 1	0	1	0	1	Register Data (LSB)
			4	Op Code Address + 2	1	0	1	0	Next Op Code
JSR		1	1	Op Code Address + 1	1	0	1	1	Jump Address (LSB)
			2	FFFF	1	1	1	[1	Restart Address (LSB)
		5	3	Stack Pointer	0	1	0	1	Return Address (LSB)
			4	Stack Pointer - 1	0	1	0	1	Return Address (MSB)
			5	Jump Address	1	0	1	0	First Subroutine Op Code
TIM	·	1	1	Op Code Address + 1	1	0	1	1	Immediate Data
		4	2	Op Code Address + 2	1	0	1	1	Address of Operand (LSB
		4	3	Address of Operand	1	0	1	1	Operand Data
			4	Op Code Address + 3	1	0	1	0	Next Op Code
AIM	EIM		1	Op Code Address + 1	1	0	1	1	Immediate Data
OIM		1	2	Op Code Address + 2	1	0	1	1	Address of Operand (LSE
		6	3	Address of Operand	1	0	1	1	Operand Data
			4	FFFF	1	1	1	1	Restart Address (LSB)
			5	Address of Operand	0	1	0	1	New Operand Data
		1	6	Op Code Address + 3	1	0	1	0	Next Op Code

Table 20 Cycle-by-Cycle Operation

(Continued)

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HD63701X0P,HD637A01X0P,HD637B01X0P------

Address Mode & Instructions	Cycles	Cycle =	Address Bus	R/₩	RD	WR	LIR	Data Bus
NDEXED			·					
JMP	1	1	Op Code Address + 1	11	0	1	1	Offset
	3	2	FFFF	1	1	1	1	Restart Address (LSB)
		3	Jump Address	1	0	1	0.	First Op Code of Jump Routin
ADC ADD		1	Op Code Address + 1	1	0	1	1	Offset
AND BIT		2	FFFF	1	1	1	1	Restart Address (LSB)
CMP EOR	4	3	IX + Offset	1	0	1	1	Operand Data
LDA ORA		4	Op Code Address + 2	1	0	1	0	Next Op Code
SBC SUB								
TST								
STA		1	Op Code Address + 1	1	0	1	1	Offset
	4	2	FFFF	1	1	1	1	Restart Address (LSB)
		3	IX + Offset	0	1	0		Accumulator Data
		4	Op Code Address + 2	1	0	1	0	Next Op Code
ADDD		1	Op Code Address + 1 FFFF		1	1		Offset
CPX LDD	-	2			o			Restart Address (LSB)
LDS LDX	5	3	IX + Offset		0			Operand Data (MSB)
SUBD		4	IX + Offset + 1	1	0	1	l o	Operand Data (LSB)
610 610		5	Op Code Address + 2 Op Code Address + 1	-	0	1		Next Op Code
STD STS		1	FFFF		1	1	1	Offset
STX	5	2	IX + Offset	o	1	o		Restart Address (LSB)
	2	4	IX + Offset + 1	0	1	0		Register Data (MSB) Register Data (LSB)
		5	Op Code Address + 2	1	o	1	Ö	Next Op Code
JSR	+	1	Op Code Address + 2	-+	0	1	1	Offset
J2H		2	FFFF		1	1	1	Restart Address (LSB)
	5	3	Stack Pointer	Ö		ò		Return Address (LSB)
		4	Stack Pointer – 1	0		o		Return Address (MSB)
		5	IX + Offset	1	o	1	o	First Subroutine Op Code
ASL ASR		1	Op Code Address + 1	1	0	- 1	1	Offset
COM DEC		2	FFFF	1	1	1	1	Restart Address (LSB)
INC LSR		3	IX + Offset	1	0	1	1	Operand Data
NEG ROL	6	4	FFFF	1	1	1	1	Restart Address (LSB)
ROR		5	IX + Offset	0	1	0	1	New Operand Data
		6	Op Code Address + 1	1	0	1	0	Next Op Code
TIM		1	Op Code Address + 1	1	0	1	1	Immediate Data
		2	Op Code Address + 2	1	0	1	1	Offset
	5	3 ·	FFFF	1	1	1	1	Restart Address (LSB)
	1	4	IX + Offset	1	0	1	1	Operand Data
		5	Op Code Address + 3	1	0	1	0	Next Op Code
CLR		1	Op Code Address + 1	1	0	1	1	Offset
		2	FFFF	1	1	1	1	Restart Address (LSB)
	5	3	IX + Offset	1	0	1	1	Operand Data
		4	IX + Offset	0	1	0	1	00
		5	Op Code Address + 2	1	0	1	0	Next Op Code
AIM EIM		1	Op Code Address + 1	1	0	1	1	Immediate Data
OIM		2	Op Code Address + 2	1	0	1	1	Offset
		3	FFFF	1	1	1	1	Restart Address (LSB)
	7	4	IX + Offset	1	0	1	1	Operand Data
		5	FFFF	1	1	1	1	Restart Address (LSB)
		6	IX + Offset	0	1	0	1	New Operand Data
		7	Op Code Address + 3	1	0	1	0	Next Op Code

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Address Mode & Instructions	Cycles	Cγcle ≇	Address Bus	R∕₩	RD	WR	LIR	Data Bus
EXTEND								
JMP		1	Op Code Address + 1	1	0	1	1	Jump Address (MSB)
	3	2	Op Code Address + 2	1	0	1	1	Jump Address (LSB)
		3	Jump Address	1	0	1	0	Next Op Code
ADC ADD TST		1	Op Code Address + 1	1	0	1	1	Address of Operand (MSB
AND BIT	4	2	Op Code Address + 2	1	0	1	1	Address of Operand (LSB)
CMP EOR	1	3	Address of Operand	1	0	1	1	Operand Data
LDA ORA SBC SUB		4	Op Code Address + 3	1	0.	1	0	Next Op Code
STA		1	Op Code Address + 1	1	0	1	1	Destination Address (MSB
	4	2	Op Code Address + 2	1	0	1	1	Destination Address (LSB)
	4	3	Destination Address	0	1	0	1	Accumulator Data
		4	Op Code Address + 3	1	0	1	0	Next Op Code
ADDD		1	Op Code Address + 1	1	0	1	1	Address of Operand (MSE
CPX LDD		2	Op Code Address + 2	1	0	1	1	Address of Operand (LSB
LDS LDX	5	3	Address of Operand	1	0	1	1	Operand Data (MSB)
SUBD		4	Address of Operand + 1	1	0	1	1	Operand Data (LSB)
	1	5	Op Code Address + 3	1	0	1	0	Next Op Code
STD STS	1	1	Op Code Address + 1	1	0	1	1	Destination Address (MSE
STX		2	Op Code Address + 2	1	0	1	1	Destination Address (LSB)
	5	3	Destination Address	0	1	0	1	Register Data (MSB)
		4	Destination Address + 1	0	1	0	1	Register Data (LSB)
		5	Op Code Address + 3	1	0	1	0	Next Op Code
JSR		1	Op Code Address + 1	1	0	1	1	Jump Address (MSB)
		2	Op Code Address + 2	1	0	1	1	Jump Address (LSB)
	6	3	FFFF	1	1	1	1	Restart Address (LSB)
	0	4	Stack Pointer	0	1	0	1	Return Address (LSB)
		5	Stack Pointer – 1	0	1	0	1	Return Address (MSB)
		6	Jump Address	1	0	1	0	First Subroutine Op Code
ASL ASR		1	Op Code Address + 1	1	0	1	1	Address of Operand (MSE
COM DEC		2	Op Code Address+2	1	0	1	1	Address of Operand (LSB
INC LSR	6	3	Address of Operand	1	0	1	1	Operand Data
NEG ROL	0	4	FFFF	1	1	1	1	Restart Address (LSB)
ROR		5	Address of Operand	0	1	0	1	New Operand Data
		6	Op Code Address + 3	1	0	1	0	Next Op Code
CLR		1	Op Code Address + 1	1	0	1	1	Address of Operand (MSI
		2	Op Code Address + 2	1	0	1	1	Address of Operand (LSB
	5	3	Address of Operand	1	0	1	1	Operand Data
		4	Address of Operand	0	1	0	1	00
		5	Op Code Address + 3	1	0	1	0	Next Op Code

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Address Mod Instructions		Cγcle #	Address Bus	R/W	RD	WR	LIR	Data Bus
MPLIED	I	<u> </u>		-		I	·	4 <u></u>
ABA ABX		1 1	Op Code Address + 1	<u> </u>	Ő	1	0	Next Op Code
ASL ASLC		'			U		Ŭ	Next Op Code
ASR CBA								
CLC CLI								
CLR CLV								
COM DEC								
DES DEX				ľ				
INC INS								
INX LSR	1 1							
LSRD ROL	· ·	1						
ROR NOP								
SBA SEC								
SEI SEV								
TAB TAP	1							
TBA TPA								
TST TSX								
TXS								
DAA XGD	. _	+- <u>1</u>	Op Code Address + 1	+	0	1	Ö	Next Op Code
	2	2	FFFF		1	1	1	Restart Address (LSB)
		1	Op Code Address + 1	$-\frac{1}{1}$	<u>'</u>	<u> </u>	0	Next Op Code
	′ · 3		FFFF		1		1	Restart Address (LSB)
	1	3	Stack Pointer + 1		l o		1	Data from Stack
PSHA PSHE		$\frac{3}{1}$	Op Code Address + 1	_ 	- 0	$-\frac{1}{1}$	1	Next Op Code
rone rone	,		FFFF	l i	1		1	Restart Address (LSB)
	4	3	Stack Pointer	, o	1	ò	1	Accumulator Data
		4	Op Code Address + 1		l o	ı ı	ò	Next Op Code
PULX		1	Op Code Address + 1	+	ō		0	Next Op Code
, OLY		2	FFFF		1		1	Restart Address (LSB)
	4	3	Stack Pointer + 1		l o		1	Data from Stack (MSB)
		4	Stack Pointer + 2		ő		1	
PSHX		1	Op Code Address + 1	- <u> </u>	0	$-\frac{1}{1}$	<u>'</u>	Data from Stack (LSB) Next Op Code
r3nx			FFFF		1		1	
	5		Stack Pointer	0		, '	1	Restart Address (LSB)
	5		Stack Pointer – 1	0		o o	1	Index Register (LSB)
				1	l o	1	0	Index Register (MSB)
070		5	Op Code Address + 1	- - 	0		1	Next Op Code
RTS			Op Code Address + 1 FFFF				1	Next Op Code
	5	3	Stack Pointer + 1	1	o		1	Restart Address (LSB)
`	5	4			0		1	Return Address (MSB)
			Stack Pointer + 2		0			Return Address (LSB)
MUL		5	Return Address	-+ '	0		0	First Op Code of Return Routi
MUL			Op Code Address + 1				1	Next Op Code
		2	FFFF	1				Restart Address (LSB)
	-	3	FFFF	1		1	1	Restart Address (LSB)
	7	4	FFFF	1			1	Restart Address (LSB)
		5	FFFF	1	1		1	Restart Address (LSB)
		6	FFFF	1			1	Restart Address (LSB)
		7	FFFF	1	1	1	1	Restart Address (LSB)

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Address Mode & Instructions	Cycles	Cγcle ≇	Address Bus	R∕₩	RD	WR	LIR	Data Bus
IMPLIED								
WAI	T	1	Op Code Address + 1	1	0	1	1	Next Op Code
		2	FFFF	1	1	1	1	Restart Address (LSB)
		3	Stack Pointer	0	1	0	1	Return Address (LSB)
		4	Stack Pointer - 1	0	1	0	1	Return Address (MSB)
	9	5	Stack Pointer-2	0	1	0	1	Index Register (LSB)
		6	Stack Pointer – 3	0	1	0	1	Index Register (MSB)
		7	Stack Pointer – 4	0	1	0	1	Accumulator A
		8	Stack Pointer – 5	0	1	0	1	Accumulator B
		9	Stack Pointer - 6	0	1	0	1	Conditional Code Register
RTI		1	Op Code Address + 1	1	0	1	1	Next Op Code
		2	FFFF	1	1	1	1	Restart Address (LSB)
		3	Stack Pointer + 1	1	0	1	1	Conditional Code Register
		4	Stack Pointer + 2	1	0] 1	1	Accumulator B
	10	5	Stack Pointer + 3	1	0	1	1	Accumulator A
	1 '	6	Stack Pointer + 4	1	0	1	1	Index Register (MSB)
		7	Stack Pointer + 5	1	0	1	1	Index Register (LSB)
		8	Stack Pointer + 6	1	0	1	1	Return Address (MSB)
		9	Stack Pointer + 7	1	0	1	1	Return Address (LSB)
		10	Return Address	1	0	1	0	First Op Code of Return Routin
SWI		1	Op Code Address + 1	1	0	1	1	Next Op Code
		2	FFFF	1	1	1	1	Restart Address (LSB)
		3	Stack Pointer	0	1	0	1	Return Address (LSB)
		4	Stack Pointer – 1	0	1	0	1	Return Address (MSB)
		5	Stack Pointer – 2	0	1	0	1	Index Register (LSB)
	12	6	Stack Pointer – 3	0	1	0	1	Index Register (MSB)
	1 12	7	Stack Pointer – 4	0	1	0	1	Accumulator A
		8	Stack Pointer – 5	0	1	0	1	Accumulator B
		9	Stack Pointer – 6	0	1	0	1	Conditional Code Register
		10	Vector Address FFFA	1	0	1	1	Address of SWI Routine (MSB)
•		11	Vector Address FFFP	1	0	1	1	Address of SWI Routine (LSB)
		12	Address of SWI Routine	1	0	1	0	First Op Code of SWI Routine
SLP	1	1	Op Code Address + 1	1	0	1	1	Next Op Code
		2	FFFF	1	1	1	1	Restart Address (LSB)
					1 1			
	4	Sleep						
		3	FFFF	1	1	1	1	Restart Address (LSB)
		4	Op Code Address + 1	1	0	1 1	0	Next Op Code

RELATIVE

BCC	BCS		1	Op Code Address + 1	1	0	1	1	Branch Offset
BEQ	BGE	3	2	FFFF	1	1	1	1	Restart Address (LSB)
BGT BLE BLT BNE BRA BVC	BHI BLS BMT BPL BRN BVS		3	Branch Address Test="1" Op Code Address + 1 · Test="0"	1	o	1	0	First Op Code of Branch Routin Next Op Code
BSR			1	Op Code Address + 1	1	0	1	1	Offset
			2	FFFF	1	1	1	1	Restart Address (LSB)
		5	3	Stack Pointer	0	1	0	1	Return Address (LSB)
			4	Stack Pointer – 1	0	1	0	1	Return Address (MSB)
			5	Branch Address	1	0	1	0	First Op Code of Subroutine

APPLICATION NOTES

The PROM Programming and Maintenance

(1) The PROM Programming and Data Retention

A ZTAT[™] MICRO's memory cell is the same as an EP-ROM device and it is programmed by hot electrons injected to the floating gate with applying high voltage at the control gate and the drain. The electrons have been trapped by the potential barrier at the polysilicon-oxide (SiO₂) by which the floating gate is completely sorrounded. The programmed cell becomes a "0".

The memory cell will be discharged by;

- (1) Heat; discharged by thermal emitting electrons
- Applied with high voltage; discharged by high electric field

Charge loss from the normal cell is negligible. But if there are some defects at the SiO₂, the cell will be rapidly discharged through the defects by heat or high voltage. Such a defective part is rejected by manufacturing screenings. The erased, or discharged, cell is a "1".

(2) Precaution of the PROM Programming

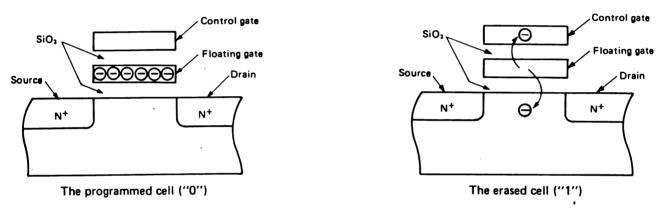
The PROM memory cell should be programmed with the

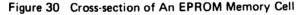
specified voltage and timing. The higher program voltage V_{PP} or the longer program pulse width t_{PW} is applied, the more quantity of electrons will be injected to the floating gate. However, a p-n junction will be broken permanently if V_{PP} is applied to more than maximum ratings. Especially V_{PP} overshoot of a PROM programmer should be checked.

Negative-noise to device pins may cause a parasitic transistor effect and reduce the breakdown voltage.

(3) Screening procedure of the ZTAT[™] MICRO

In general, any standard manufacturing screening of semiconductor devices will make initial failures rejected and improve reliability. The bake procedure is the standard screening for EPROM devices, which accelerates any electron leakage at the floating gate described before (see (1)). The manufacturer, of course, tests the CPU, RAM, I/O, other logic functions and the PROM of the ZTAT[™] MICRO after screening at wafer site, and rejects any devices which do not pass the tests. If users require improving reliability of the ZTAT™ MICRO's PROM portion, it is recommended that users also carry out the screening procedure shown in Fig. 31 after programming.





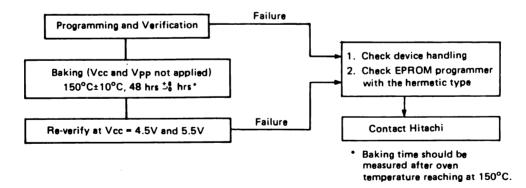


Figure 31 Recommended Screening Procedure of the ZTATTM MICRO

- (Caution) If the user experiences several consecutive programming failures, from same EPROM programmer, after the recommended screening procedure shown in Fig. 31, then call Hitachi.
- (4) EPROM programmers and socket adapters EPROM programmers and socket adapters which are recommended for the HD63701X0 are shown Table 21.
 - A socket adapter is a tool to convert from 64-pin socket to standard 24-pin socket.

EPROM Prog	grammer	Socket Ad	lapter
Maker	Type No.	Maker	Type No.
	12A/121B	Hitachi Ltd.	H67PWA01A
DATA I/O (U.S.A.)	22A/22B 29A/29B	Data I/O	HD63701X0 (for 29A/29B)
AVAL CORP. (JAPAN)	PKW-1000 PKW-7000	Hitachi Ltd.	H67PWA01B
Minato Electronics Inc. (JAPAN)	M1863 M1866 7GU-2700	Hitachi Ltd.	H67PWA01B

Table 21 EPROM Programmers and Socket Adapters	for	ers fo	' the	HD63701X	0
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• Write only Register

When a write-only register such as the DDR of the port is read by the MPU, "\$FF" always appears on the data bus. Note that when an instruction which reads the memory contents and does some arithmetic operation on the contents of the write-only register, it always gets \$FF as the arithmetic and logical results. AIM, OIM and EIM instructions are unable to apply especially for the bit manipulation of the DDR of the I/O port.

• Trap Interrupt

When execution an RTI instruction at the end of the interrupt routine, trap interrupt different from other interrupts returns to the address where the trap interrupt was generated. Attention is necessary when using several trap interrupts in the program. See Fig. 32 and 33 for details.

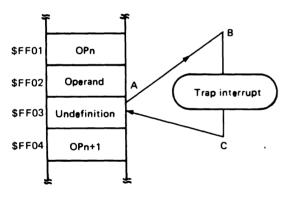


Figure 32 Fetching an Undefined Op-code

After executing OPn instruction, the HD63701X0 fetches and decodes and undefined op-code inside to generate a trap interrupt. When RTI instruction is executed in this trap interrupt servicing routine, the HD63701X0 will set \$FF03 in PC, fetch the undefined code again, generate a trap interrupt and repeat ABC endless-loop.

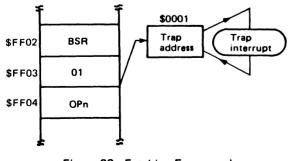
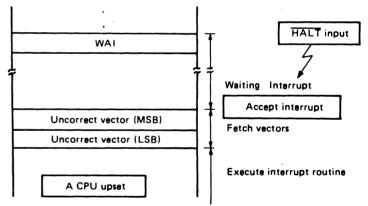


Figure 33 Fetching Erroneously

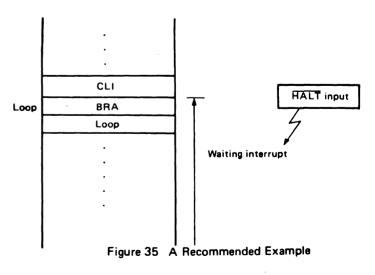
After performing BSR instruction, the branch destination address is output on an address bus to fetch the first op-code of a subroutine. If \$0001 is output as an address by some mistake the HD63701X0 decodes it inside and generates a trap interrupt. When RTI instruction is performed in this trap interrupt servicing routine, the HD63701X0 will set \$0001 in PC and start from this address, which causes a trap interrupt again and repeat this endless-loop.

• Precaution for using WAI instruction

If HALT turns "Low" in WAI execution, a CPU upset may occur since the correct vector will not be fetched after the halt state has been released. It is recommended to use BRA instruction etc. for software interrupt before HALT turns "Low" shown Fig. 35.









Power-on Reset

At power-on it is necessary to hold $\overline{\text{RES}}$ "low" to reset the internal state of the device and to provide sufficient time for the oscillator to stabilize. Pay attention to the following.

• Just after power-on, the MPU doesn't enter reset state until the oscillation starts. This is because the reset signal is input internally, with the clocked synchronization as shown below.

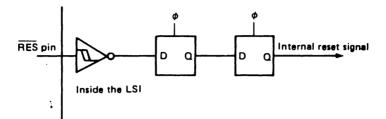


Figure 36 Reset Circuit

Thus, just after power-on the LSI state (I/O port, mode condition etc.) is unstable until the oscillation starts. If it is necessary to inform the LSI state to the external devices during this period, it needs to be done by the external circuits.

Board Design of Oscillation Circuits

Keep the following in mind when connecting a crystal resonator to XTAL and EXTAL pins of the HD63701X0.

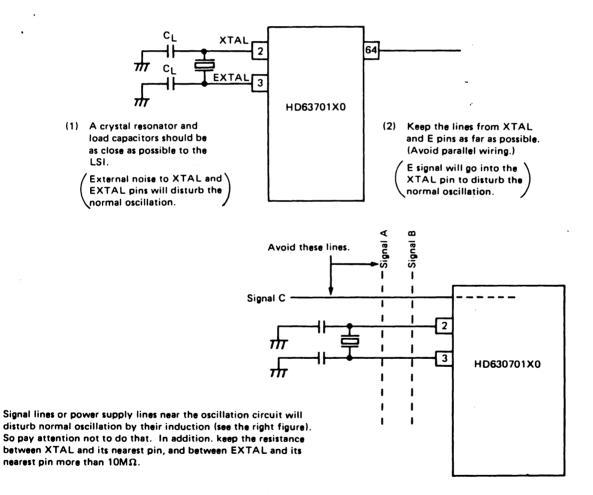
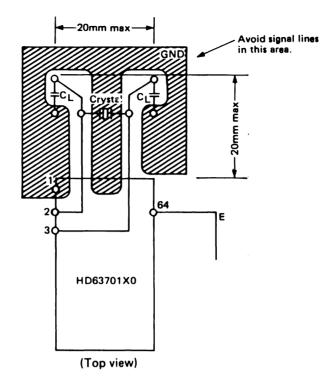
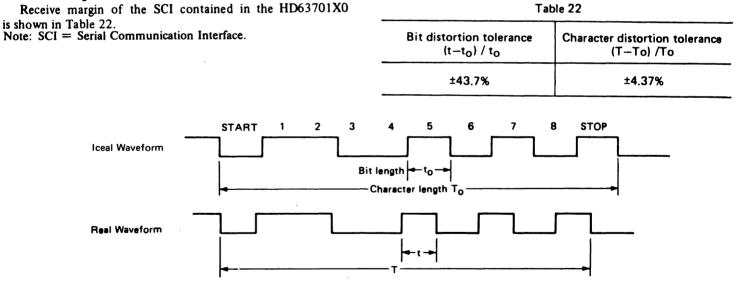


Figure 37 Precaution on Board Design of Oscillation Circuits





• Receive Margin of the SCI



• Cautions for OCF clearing in the TCSR of Timer 1

OCF is cleared by writing to the OCR after reading the TCSR at OCF = "1". OCF, however, is not cleared under following conditions;

- (1) The TCSR is read at OCF = "0", and then OCF is set (when the comparematch is found between the FCR and the OCR) before writing to the OCR.
- (2) The TCSR is read at OCF = "1", and then the comparematch is found between the FCR and the OCR at the OCR write cycle (OCF clear cycle).

HD63701X0P,HD637A01X0P,HD637B01X0P-

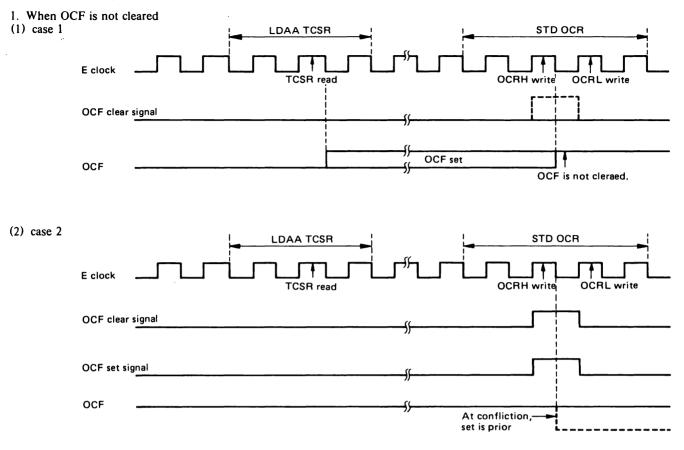


Fig. 39

2. Countermeasures

Following countermeasures against the above cases should be taken to avoid the comparematch during the TCSR read to the OCR write.

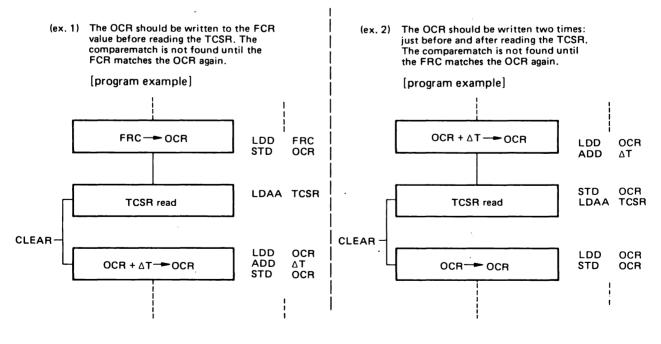


Fig. 40



PACKAGE DIMENSIONS (Unit: mm)

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• DP-64S

